

Theory of Rashba splitting in quantum-well states

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Collaborator

Experiment : R. Noguchi, K. Kuroda, T. Kondo

Theory : T. Ozaki

- R. Noguchi, K. Kuroda, M. Kawamura, K. Yaji, A. Harasawa, T. Iimori, S. Shin, F. Komori, T. Ozaki, T. Kondo, PRB 104, L180409 (2021).
- M. Kawamura, T. Ozaki, In preparation.

OpenMX developer's meeting
2023/11/10

Outline

- Introduction
 - Rashba effect and its application
 - Large Rashba-parameter materials
- Quantum well state in Ag few MLs on Au(111)
 - Computational result
 - Discussion
- Theory of Rashba splitting
 - Spin-orbit interaction and intrinsic magnetic field
 - Tight-binding model and solution
- Application of model to QWS of Ag/Au(111)
- Summary

Rashba effect

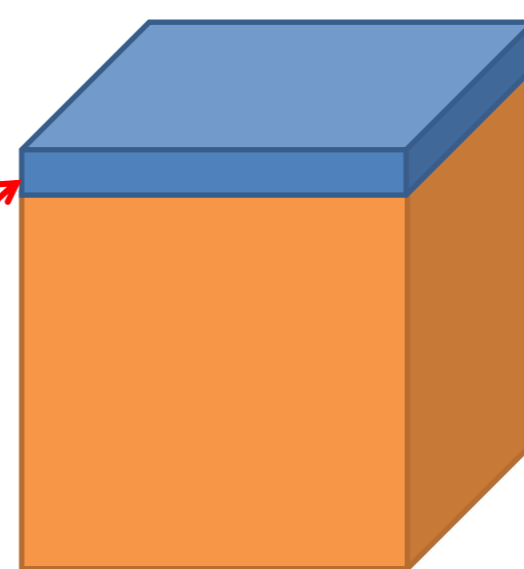
Y. Bychkov, E. Rashba JETP Lett. **39**, 78 (1984).

Hamiltonian with spin-orbit interaction

$$\hat{H} = -\frac{\nabla^2}{2} + V(r) + \frac{2}{c^2} (\nabla V(r) \times \mathbf{p}) \cdot \mathbf{s}$$

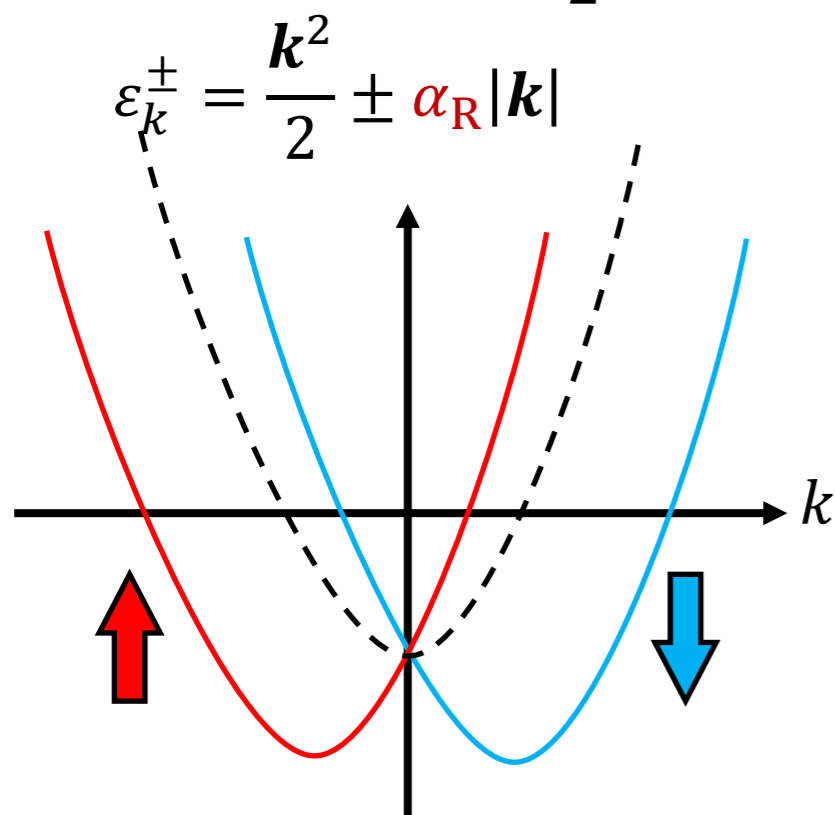
Confined 2D (Nearly Free) electrons

$$\hat{H}(\mathbf{k}) = \frac{\mathbf{k}^2}{2} + 2\alpha_R (\mathbf{e}_z \times \mathbf{k}) \cdot \mathbf{s}$$



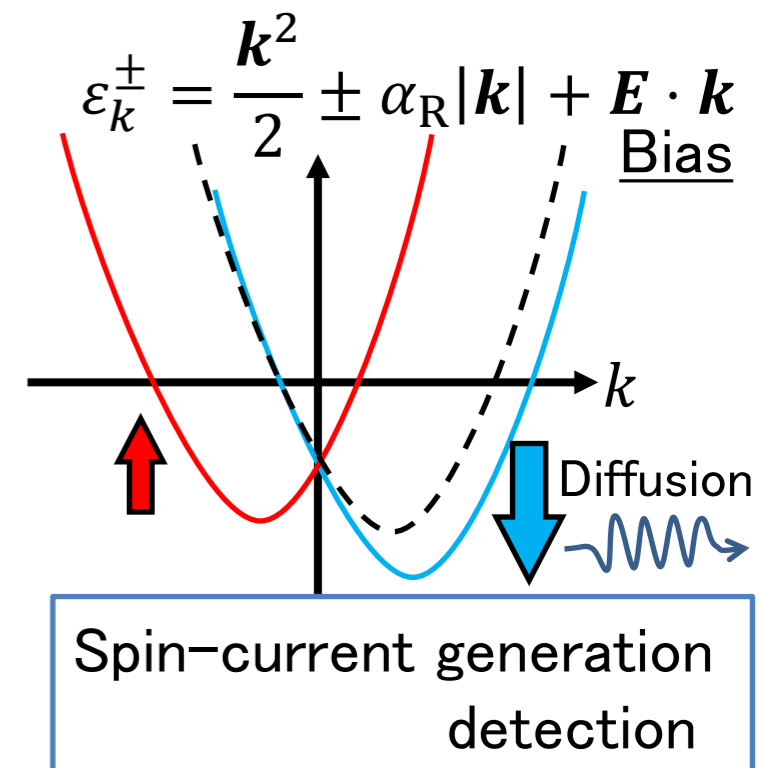
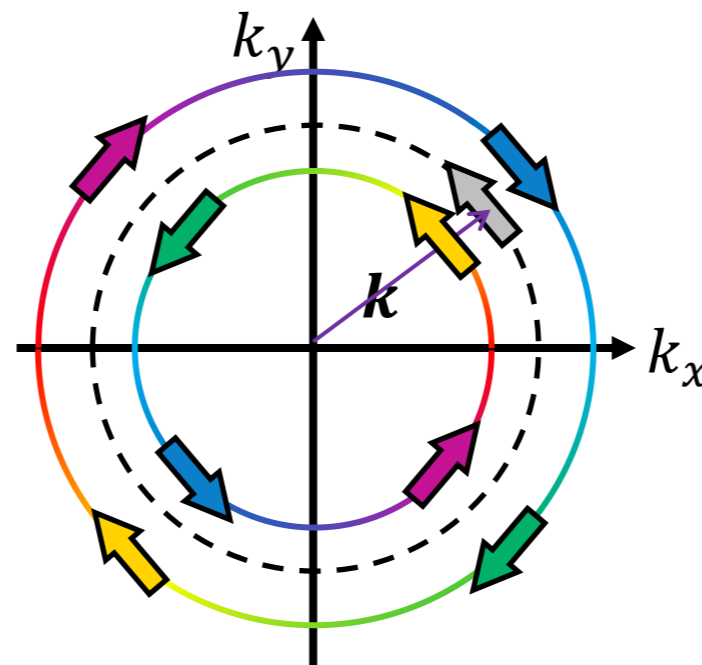
Inversion
asymmetric
potential

Application



$$\hat{H}_R(\mathbf{k}) = \mathbf{B}_R(\mathbf{k}) \cdot \mathbf{s}$$

$$\mathbf{B}_R(\mathbf{k}) \equiv \alpha_R (\mathbf{e}_z \times \mathbf{k})$$

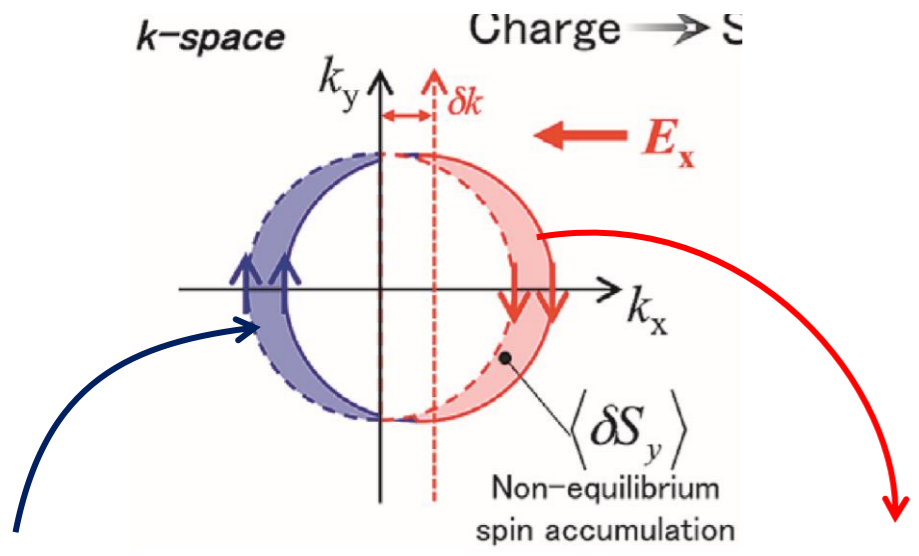


Intro

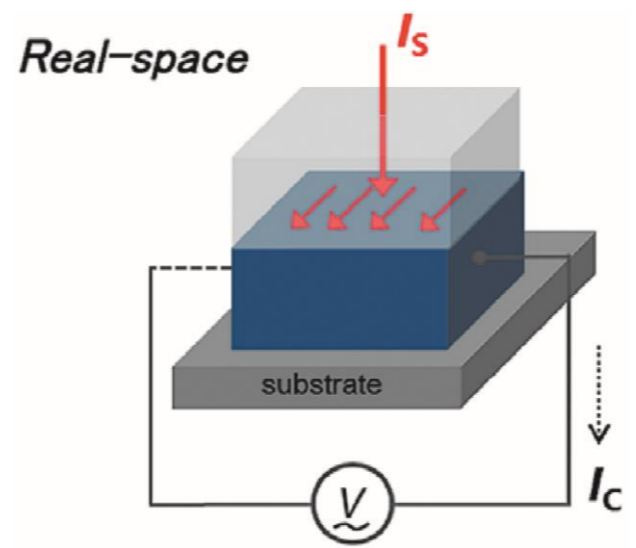
Application of Rashba effect

※ Only large Fermi surface is drawn

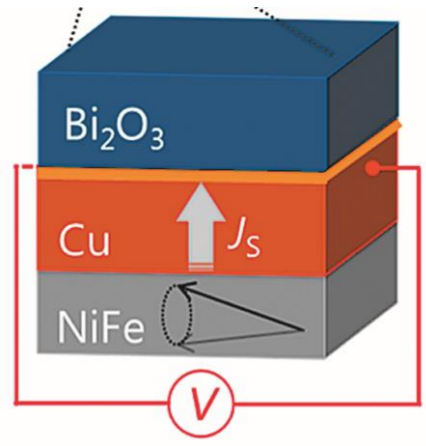
Generate spin current



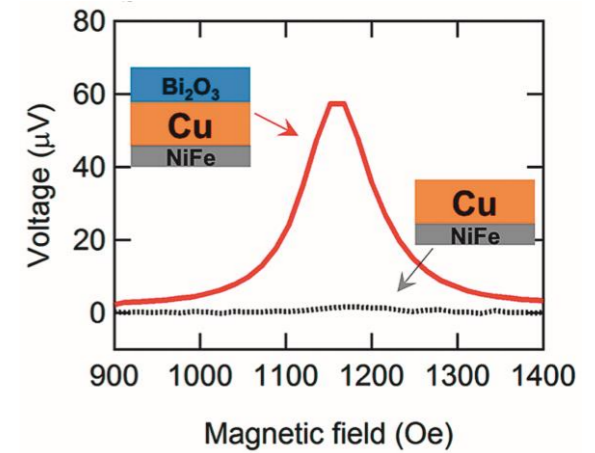
Detect spin current



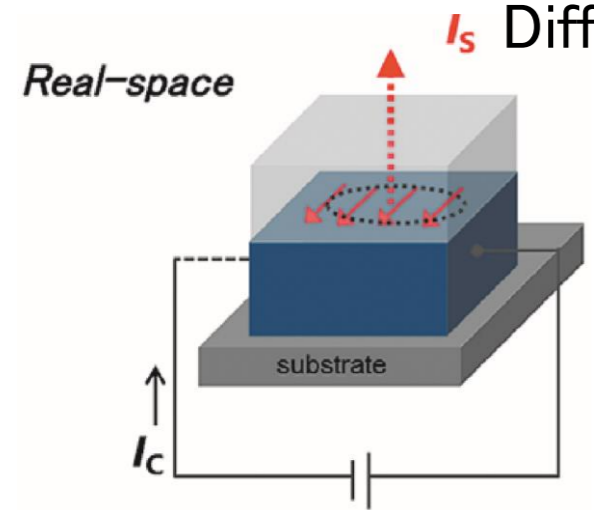
Measurement of Spin current \rightarrow Charge current



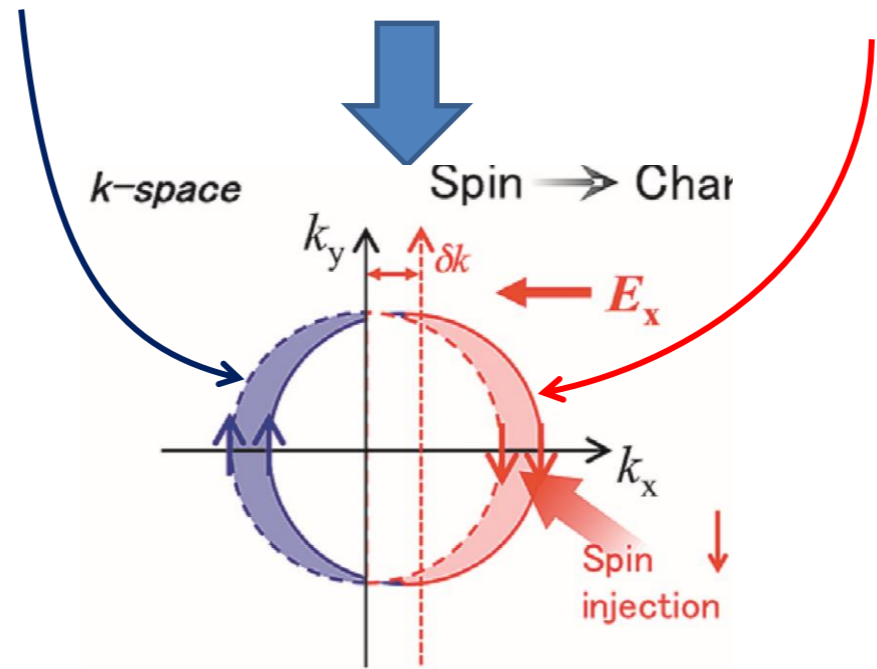
No inverse spin Hall effect
No spin current in Bi_2O_3



I_s Diffuse



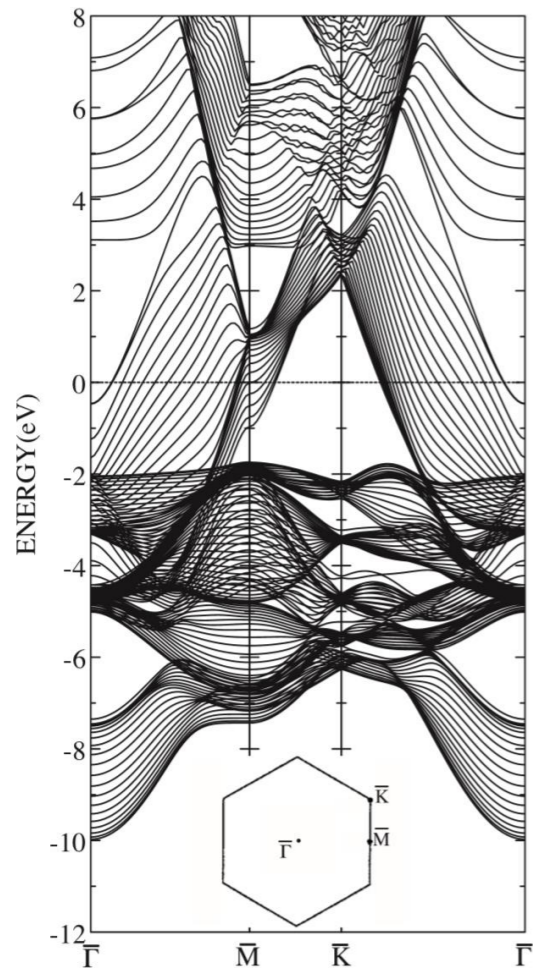
Spin \rightarrow Char



Origin of potential gradient

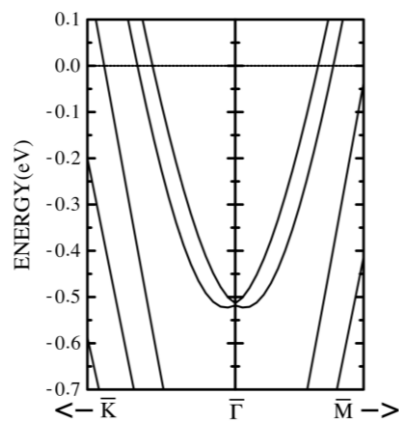
Au(111), Ag(111), Sb(111)

23 layer slab



Large SOI +
Asymmetry of WF

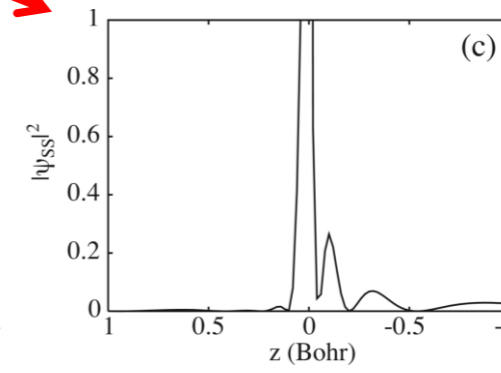
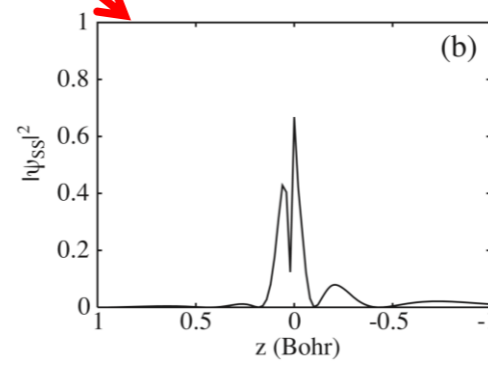
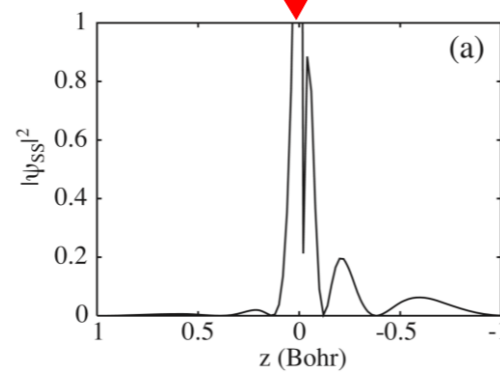
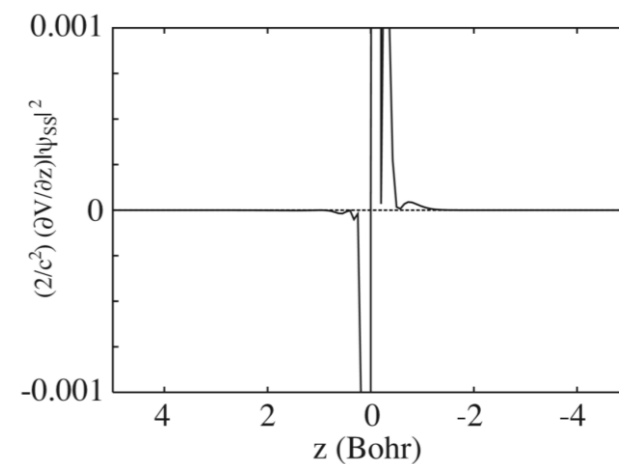
M. Nagano, *et al.*, J. Phys.: Condens. Matter **21**, 064239 (2009).



- SOC : Second variational
- FLAPW

$$\Delta\varepsilon_R = \langle \psi_{SS}^{k_{\parallel}} | \hat{H}_R | \psi_{SS}^{k_{\parallel}} \rangle = |\mathbf{k}_{\parallel}| \int d^3r \frac{2}{c^2} \frac{\partial V}{\partial z} |\psi_{SS}^{k_{\parallel}}|^2$$

		${}_{71}\text{Au}(111)$	${}_{47}\text{Ag}(111)$	${}_{51}\text{Sb}(111)$
Δk_R (10^{-3} \AA^{-1})	$\bar{\Gamma}\bar{M}$	27.8	—	20.5
	$\bar{\Gamma}\bar{K}$	27.8	—	21.2
ζ_l (eV)	p	6.34	1.90	2.27
	d	0.79	0.27	0.52
Component (%)	s	1.3	0.7	3.3
	p	4.7	4.6	9.8
	d	2.5	0.8	—



Material with Large Rashba Splitting

Au(111) surface state

S. LaShell, *et al.*, PRL **77**, 3419 (1996).

$$\alpha_R = 0.33 \text{ eV} \cdot \text{\AA}$$

Bi surface alloy

$\sqrt{3} \times \sqrt{3}$ R30° Bi/Ag(111)

C. Ast, *et al.*, PRL **98**, 186807 (2007).

$$\alpha_R = 3.05 \text{ eV} \cdot \text{\AA}$$

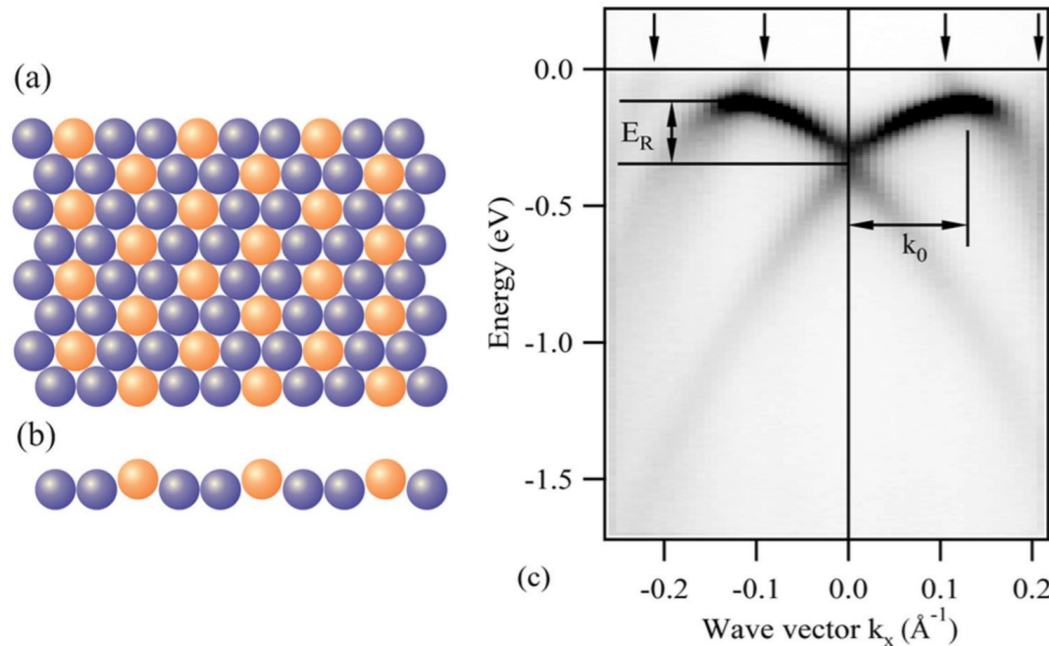


Table 1j Selected materials and parameters characterizing spin band splitting: the momentum offset k_0 (\AA^{-1}), Rashba energy E_R (meV) and Rashba parameter α_R (eV \AA).

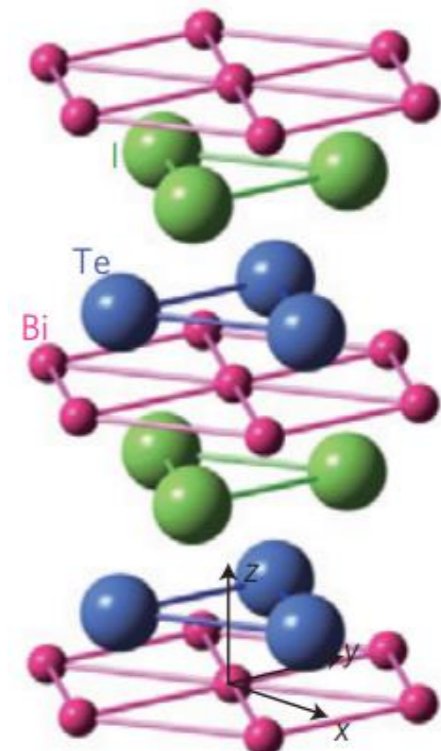
Sample	k_0	E_R	α_R	Reference
Surface state				
Au(111)	0.012	2.1	0.33	5
Bi(111)	0.05	14	0.55	16
1/3 ML Bi on Ag surface alloy	0.13	200	3.05	7
Interface				
InGaAs/InAlAs	0.028	<1	0.07	4
QW state				
Pb thin film (6–22 ML)	0.035	$\lesssim 10$	0.04	36
Bi thin film (7–40 BL)	-	-	-	18,37
1 ML Bi on Cu	N/A	N/A	2.5	20
Bulk				
BiTel	0.052	100	3.8	This work

For the Bi thin-film system in refs 18,37, the splitting was observed only for the surface states, not for the QW subband states. ML, monolayer.

Table 2

Rashba parameters in the Bi/ M alloys: α_R is the Rashba coefficient, E_R the Rashba energy, k_R the Rashba momentum offset.

M	Cu	Ag	Au	Ni	Co	Fe
Upper splitting						
$k_R(\text{\AA}^{-1})$	0.036	0.075	0.046	0.067	0.077	0.082
$E_R(\text{eV})$	0.068	0.123	0.044	0.135	0.140	0.139
$\alpha_R(\text{eV} \cdot \text{\AA})$	3.76	3.28	1.91	4.05	3.71	3.40
Lower splitting						
$k_R(\text{\AA}^{-1})$	0.072	0.124	0.206	0.094	0.113	0.115
$E_R(\text{eV})$	0.093	0.177	0.168	0.107	0.112	0.067
$\alpha_R(\text{eV} \cdot \text{\AA})$	2.59	2.85	1.63	2.28	1.98	1.17



K. Ishizaka, *et al.*, Nature Materials **10**, 521 (2011).

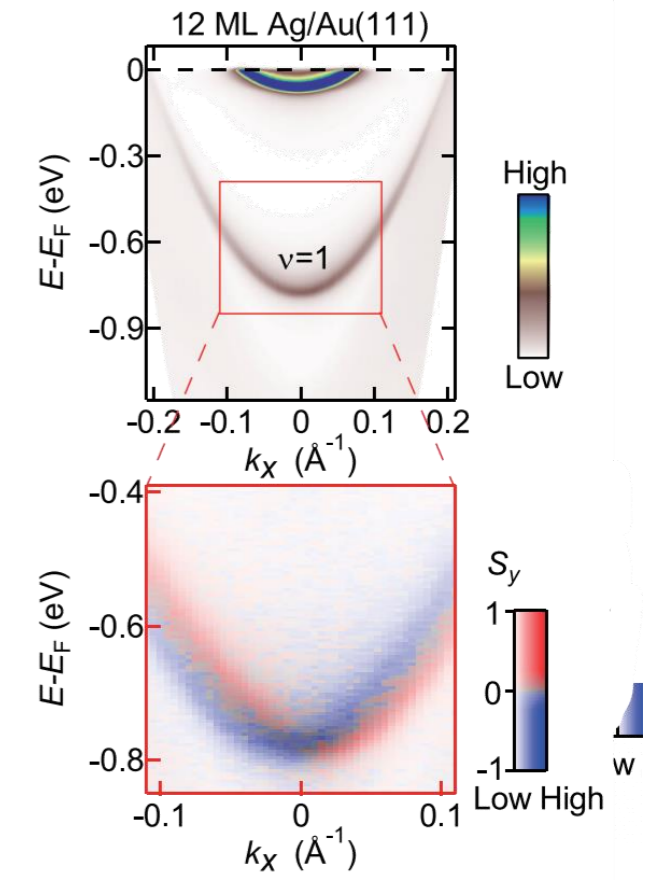
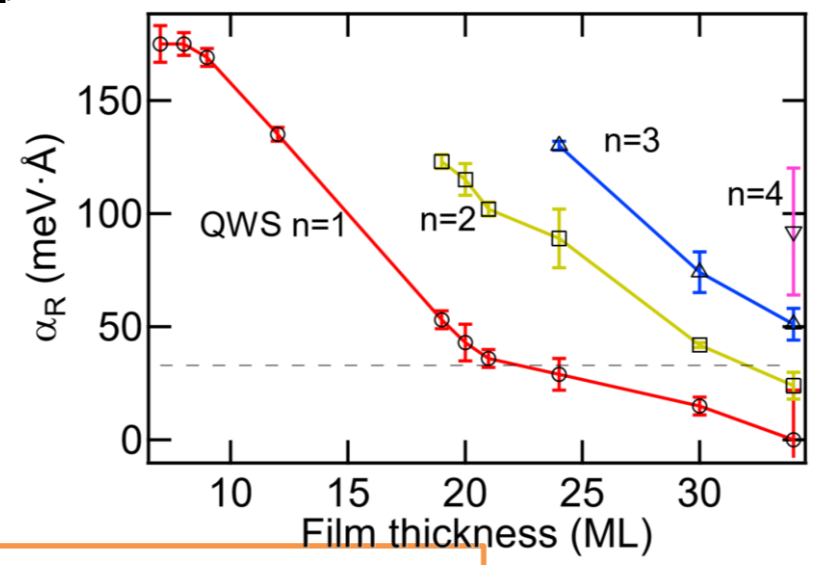
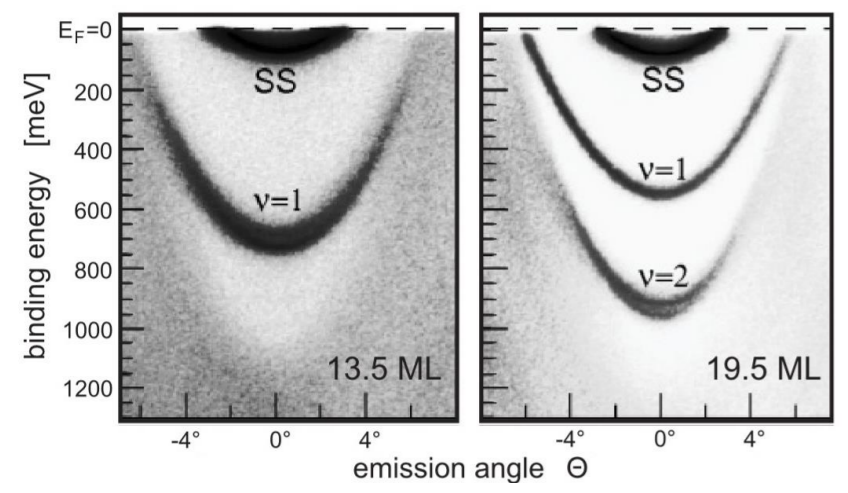
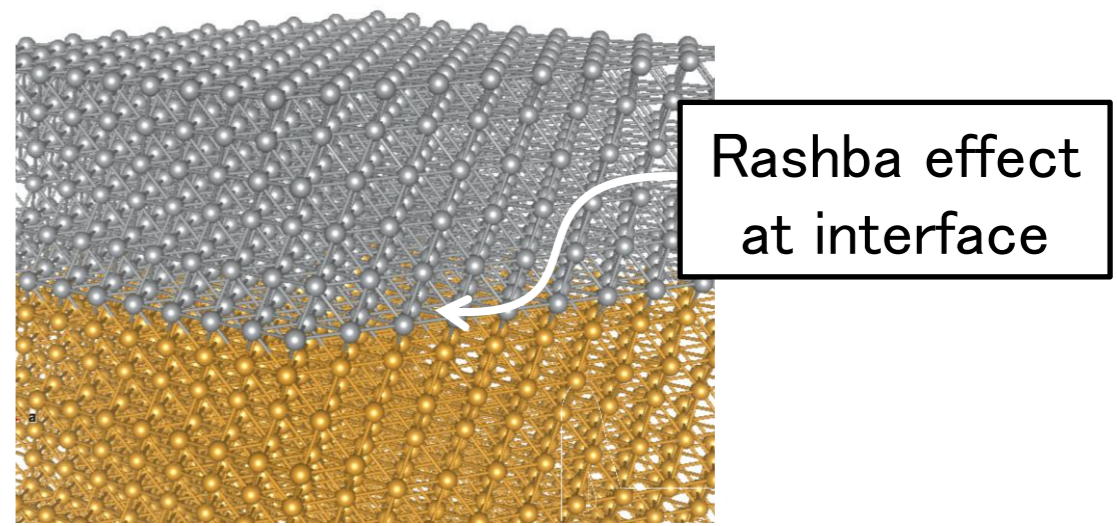
N. Yamaguchi,
F. Ishii, J. Crys.
Growth **468**,
688 (2017)

Intro

High-resolution spin-decomposed ARPES
 Au(111) : $\alpha_R = 330 \text{ meV}\cdot\text{\AA}$ K. Yaji *et al.*,
 Ag(111) : $\alpha_R = 31 \text{ meV}\cdot\text{\AA}$ PRB 98, 041404 (2018).

Ag/Au(111) : Quantum well states confined in Ag region

T. Miller, *et al.*, PRL 61, 1404 (1988). F. Forster, *et al.* PRB 84, 075412 (2011).



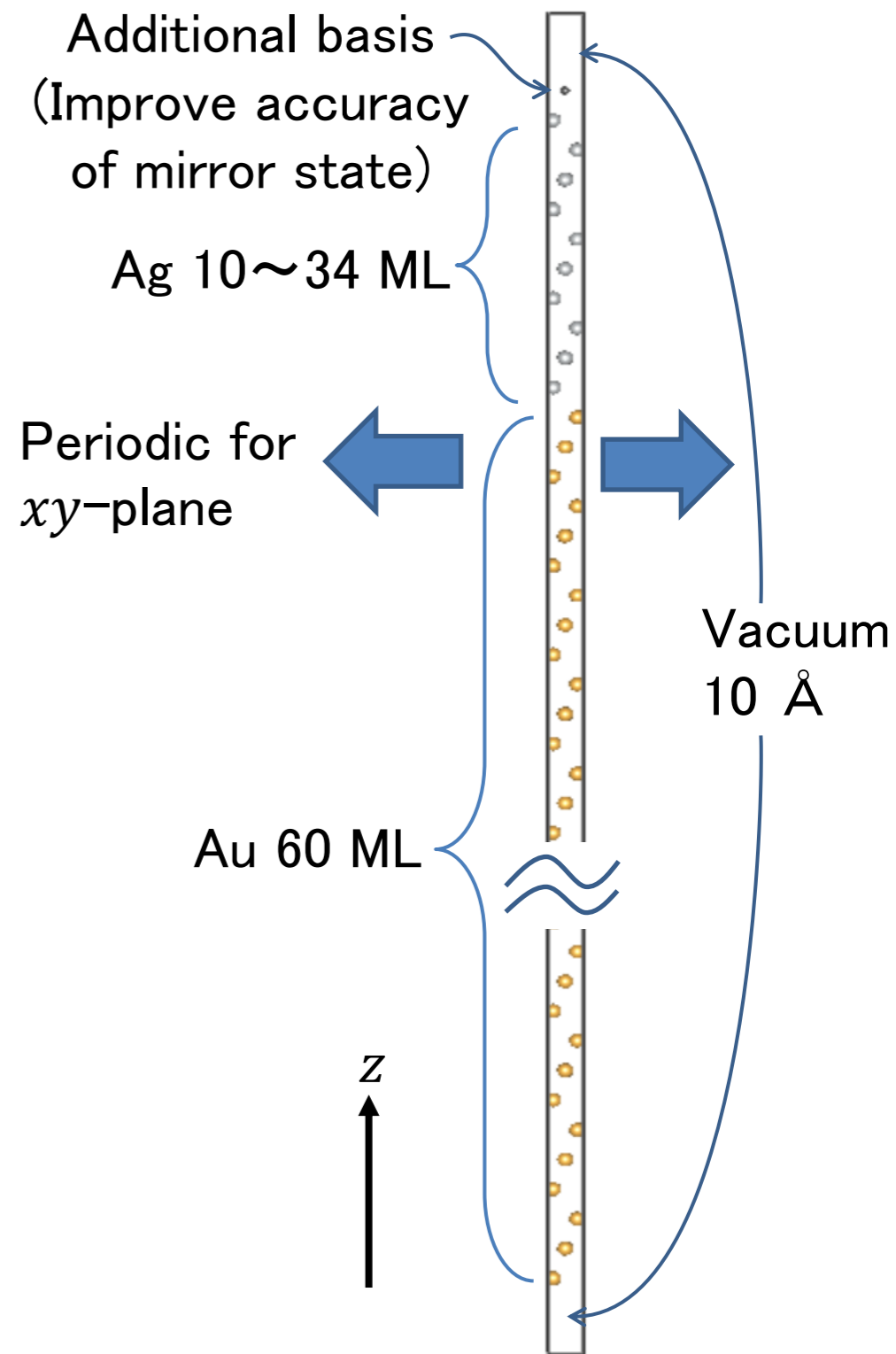
Purpose : Reveal the mechanism of this trend

- The shape of the quantum well state
- The effect of Au-SOI at the boundary atom
- How well states (not surface state) feel the Rashba effect

QWS in Ag/Au(111)

Example

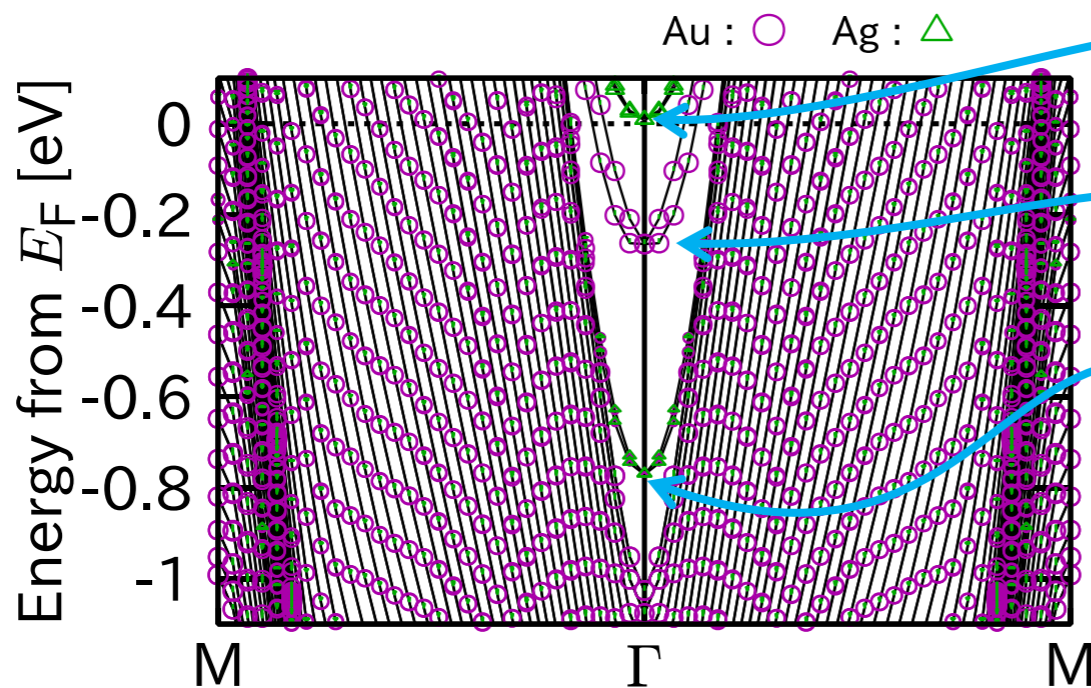
- DFT code : OpenMX
- GGA-PBE functional
- ρ cutoff : 300 Ry
- Broadening : 5000 K (0.03 Ry)
- \mathbf{k} -grid : $14 \times 14 \times 1$
- Spin-orbit
- Au 60 ML
 - Basis
 - Au7.0-s4p3d2f1
 - Ag7.0-s2p2d2f1
 - With structure optimization



Band structure and well states

Ag
Surface
state

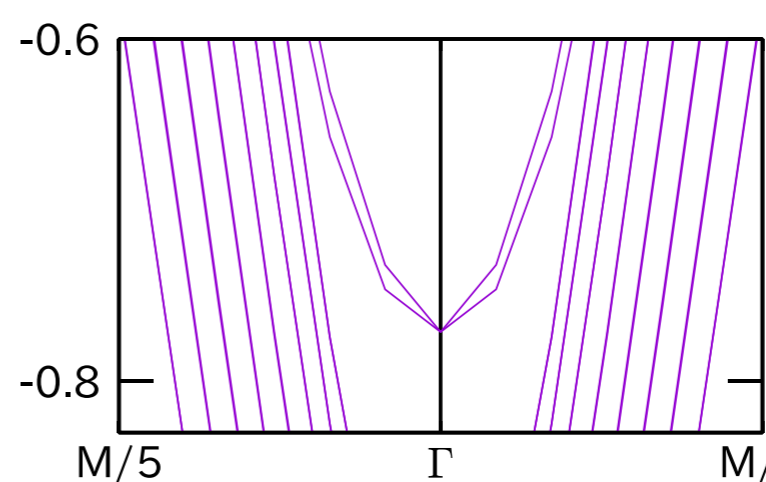
Ag10ML
on
Au(111)



Au surface
state

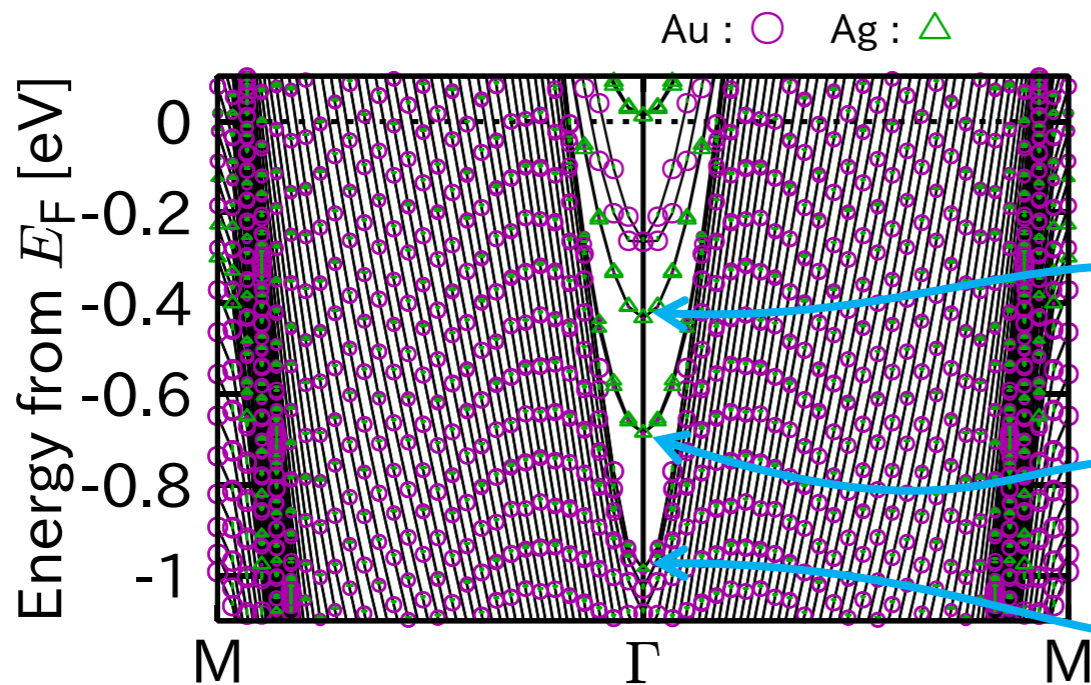


$n = 1$



quantum well state
(QWS)

Ag24ML
On
Au(111)



$n = 1$ QWS



$n = 2$ QWS

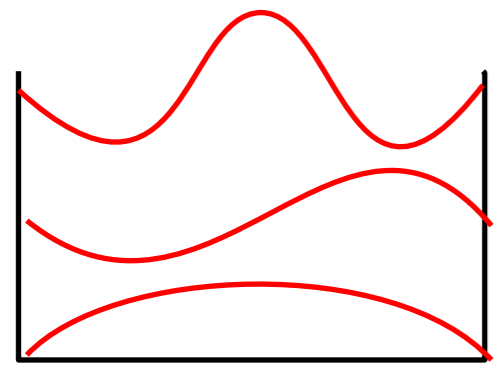


$n = 3$ QWS

Energy level of QWS

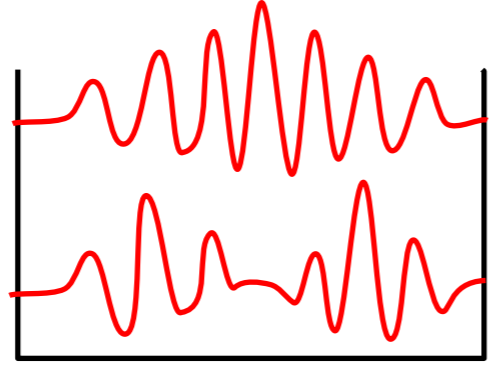
Discuss

Normal QWS



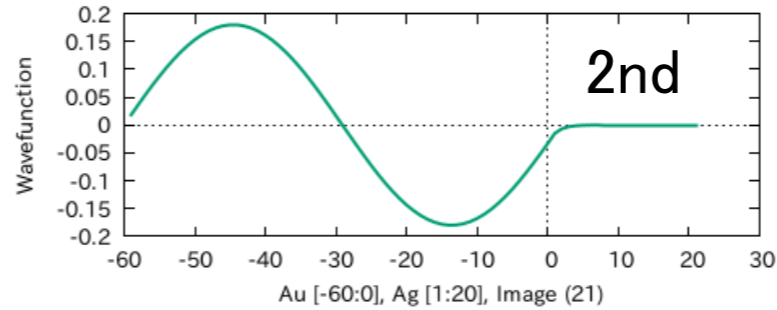
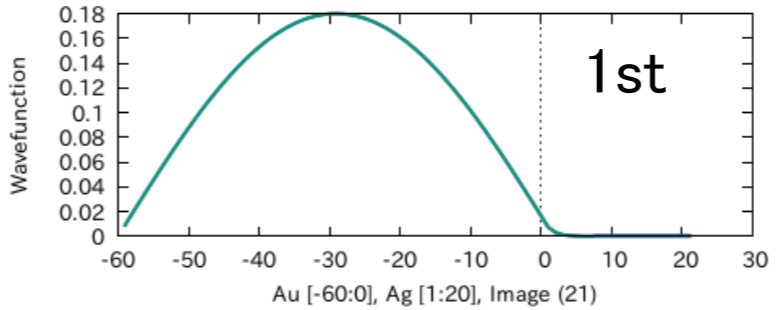
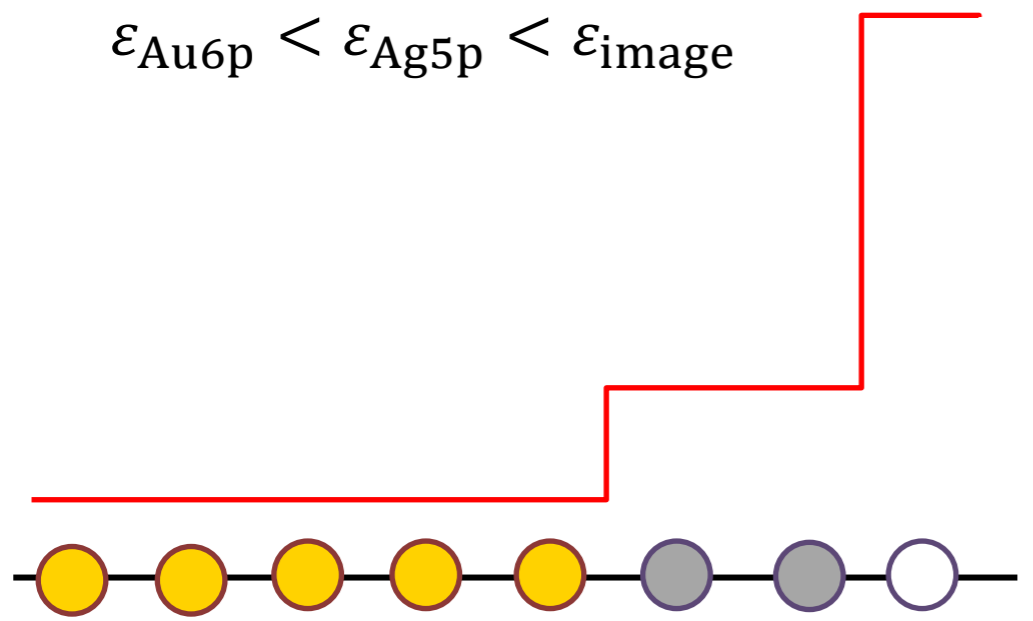
$$\epsilon_1 < \epsilon_2 < \epsilon_3 < \dots$$

This case



$$\epsilon_1 > \epsilon_2 > \epsilon_3 > \dots$$

$$\epsilon_{\text{Au}6p} < \epsilon_{\text{Ag}5p} < \epsilon_{\text{image}}$$



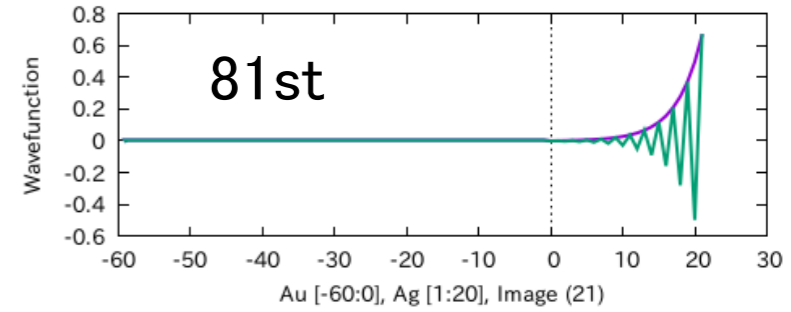
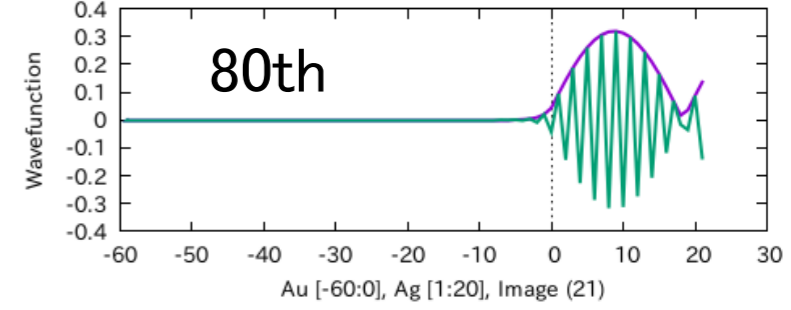
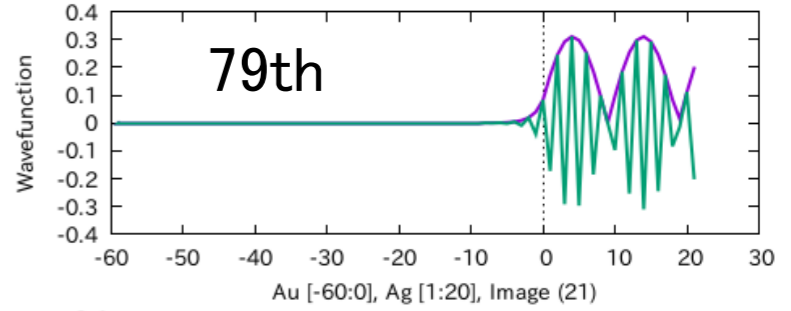
Au : 60 sites
 Ag : 20 sites
 Image : 1 site

$$t = -3$$

$$\epsilon_{\text{Au}} = 0$$

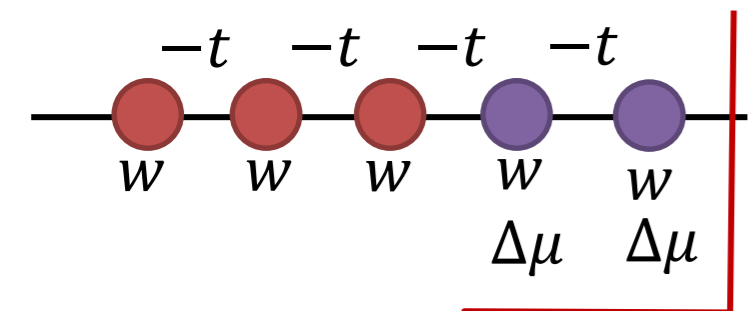
$$\epsilon_{\text{Ag}} = 2$$

$$\epsilon_{\text{image}} = 6$$



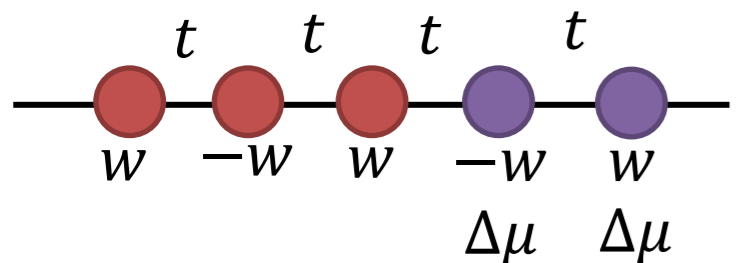
Discuss

Tight-binding

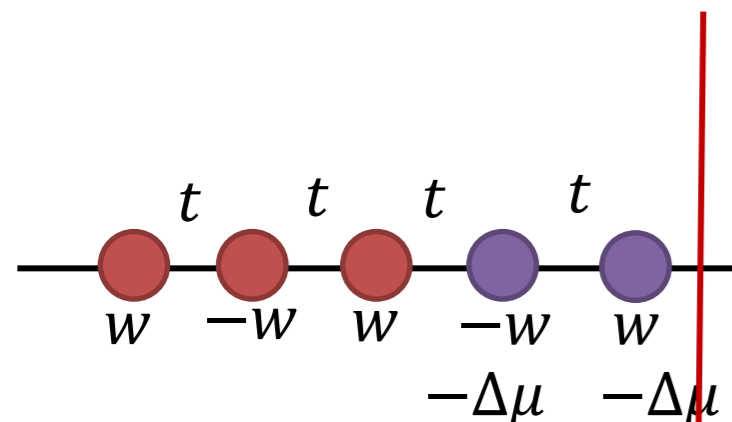


$$H = \begin{pmatrix} 0 & -t & 0 & 0 & 0 \\ -t & 0 & -t & 0 & 0 \\ 0 & -t & 0 & -t & 0 \\ 0 & 0 & -t & \Delta\mu & -t \\ 0 & 0 & 0 & -t & \Delta\mu \end{pmatrix}$$

Same spectrum



$$H_{\text{staggered}} = \begin{pmatrix} 0 & t & 0 & 0 & 0 \\ t & 0 & t & 0 & 0 \\ 0 & t & 0 & t & 0 \\ 0 & 0 & t & \Delta\mu & t \\ 0 & 0 & 0 & t & \Delta\mu \end{pmatrix}$$



$$H_{\text{stag,inv}} = \begin{pmatrix} 0 & t & 0 & 0 & 0 \\ t & 0 & t & 0 & 0 \\ 0 & t & 0 & t & 0 \\ 0 & 0 & t & -\Delta\mu & t \\ 0 & 0 & 0 & t & -\Delta\mu \end{pmatrix} = -H$$

Inverted spectrum

Result

Rashba split vs ML

Reproduce experimental results

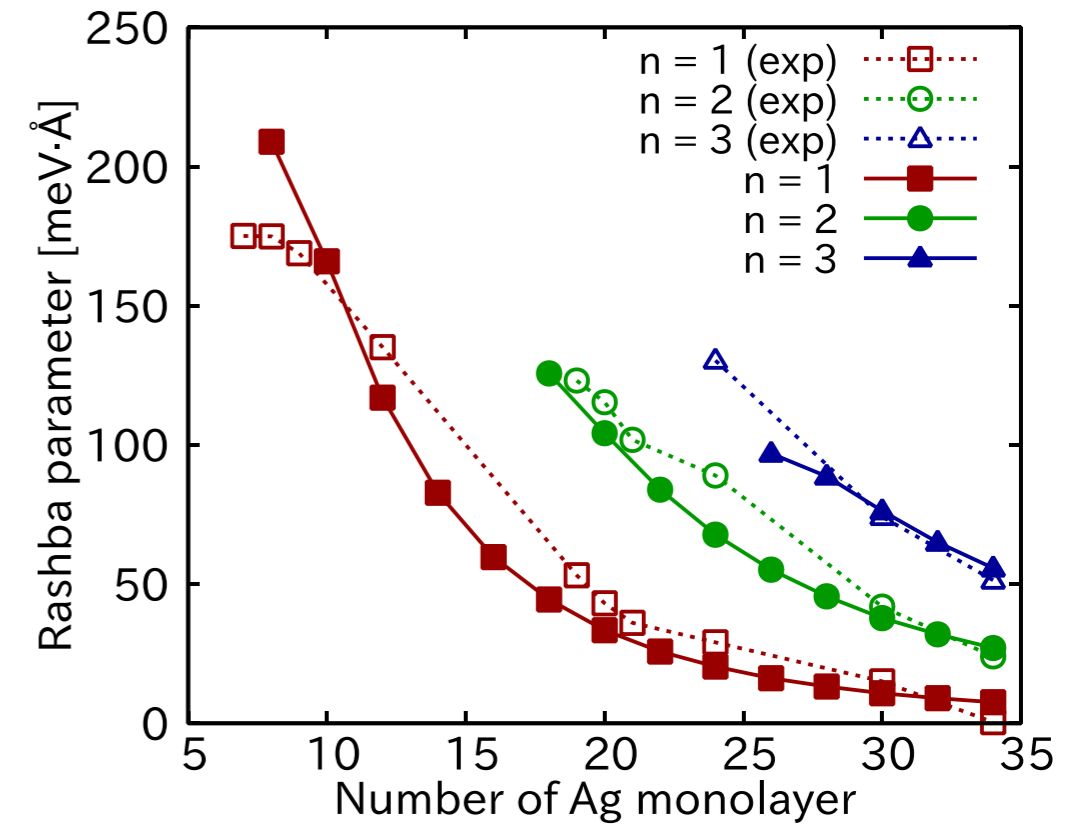
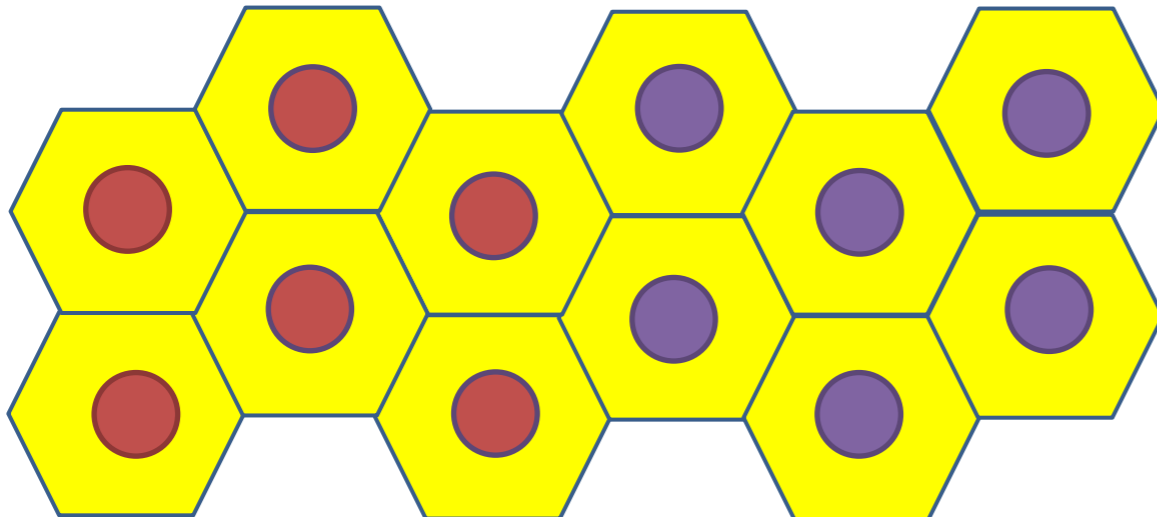
Next

Investigate ML and well state dependence of the splitting

$$\hat{H} = -\frac{\nabla^2}{2} + V(r) + \frac{2}{c^2} (\nabla V(r) \times \mathbf{p}) \cdot \mathbf{s}$$

Rashba splitting from SOI term

$$\Delta \varepsilon_R \approx \int d^3r \frac{2}{c^2} (\nabla V(r) \times \mathbf{p}) \cdot \mathbf{s} |\varphi(r)|^2$$

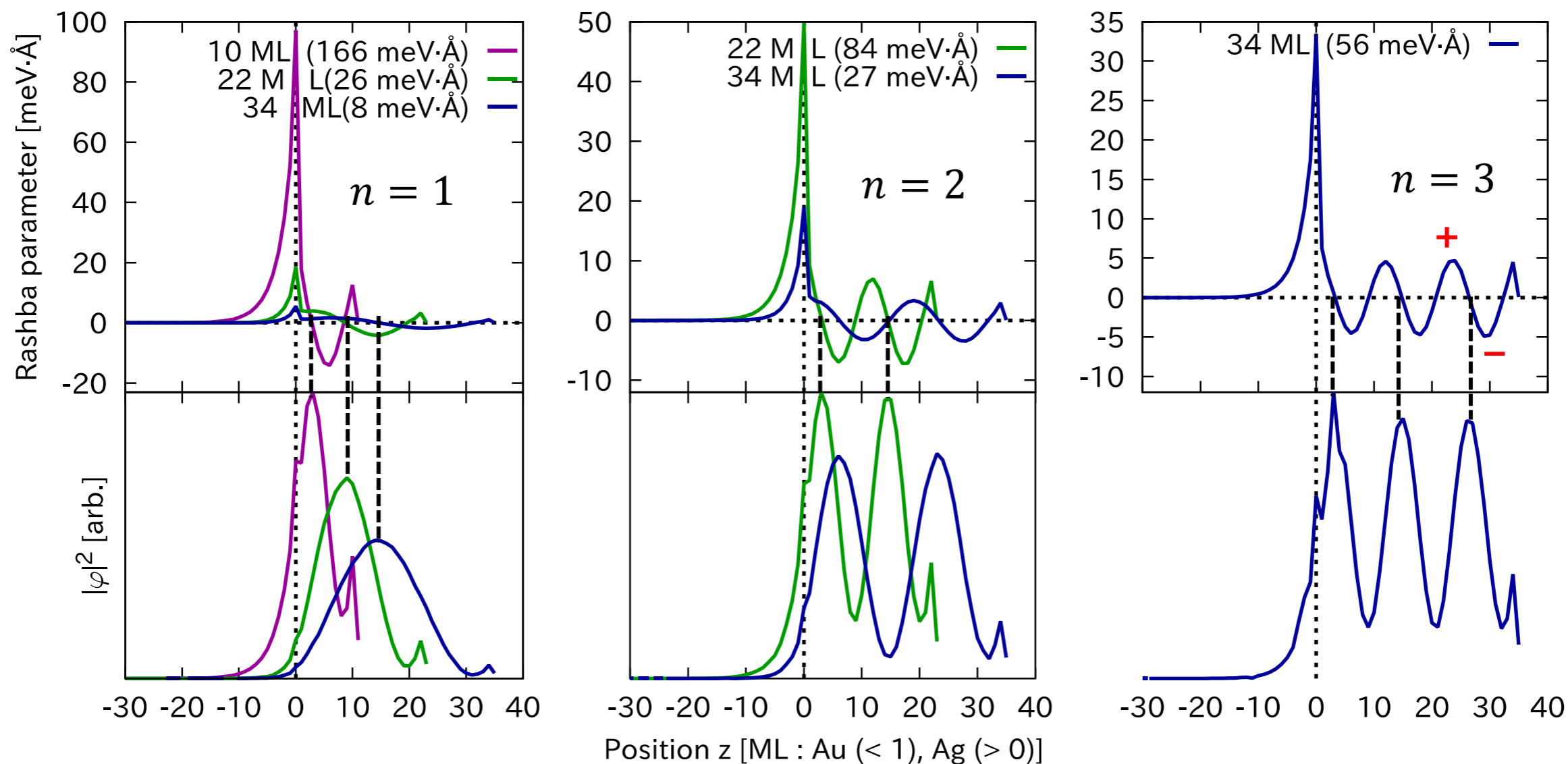


Decompose integration into contributions from each atom

⊗ Decomposition method is **not unique**

Split vs $|\varphi(r)|^2$

$$\Delta\varepsilon_R = \int d^3r \frac{2}{c^2} (\nabla V(r) \times \mathbf{p}) \cdot \mathbf{s} |\varphi(r)|^2$$



Peak of $|\varphi(r)|^2 \rightarrow$ Node of decomposed splitting $\Delta\varepsilon_i$

Slope of $|\varphi(r)|^2 \rightarrow$ Peak of decomposed splitting $\Delta\varepsilon_i$ (Opposite sign)

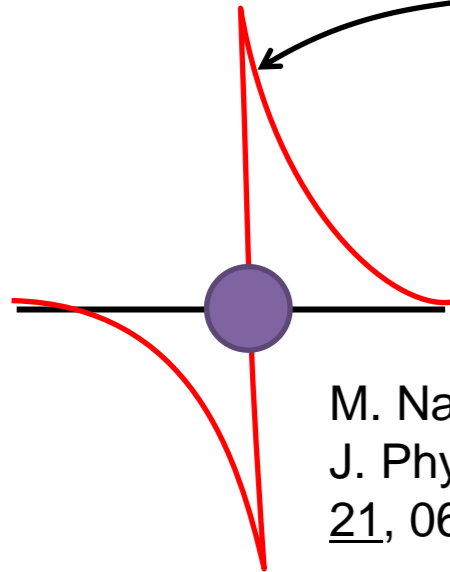
Result

Mechanism

$$\Delta\varepsilon_R = \int d^3r \frac{2}{c^2} (\nabla V(\mathbf{r}) \times \mathbf{p}) \cdot \mathbf{s} |\varphi(\mathbf{r})|^2$$

$$\approx |\mathbf{k}_{\parallel}| \int d^3r \frac{1}{c^2} \frac{\partial V}{\partial z} |\varphi(\mathbf{r})|^2$$

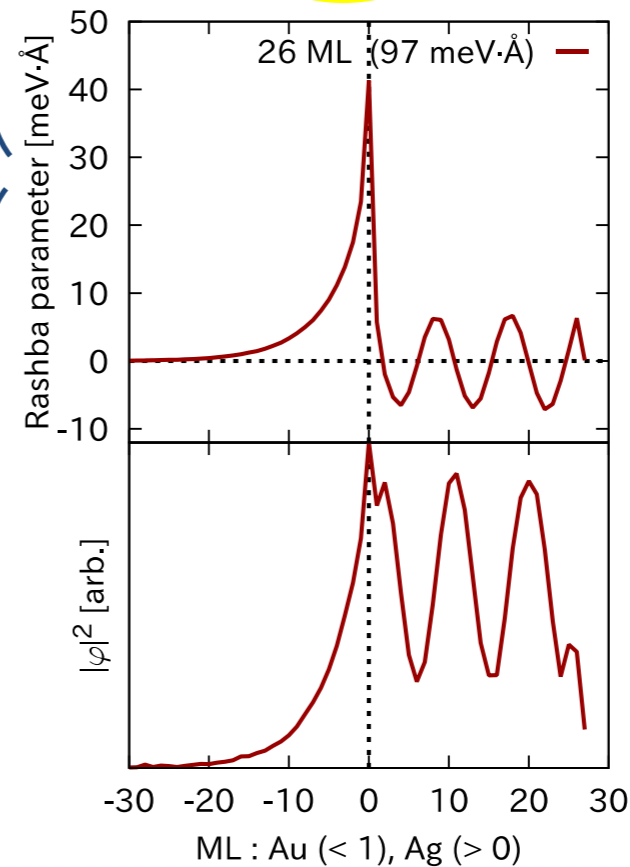
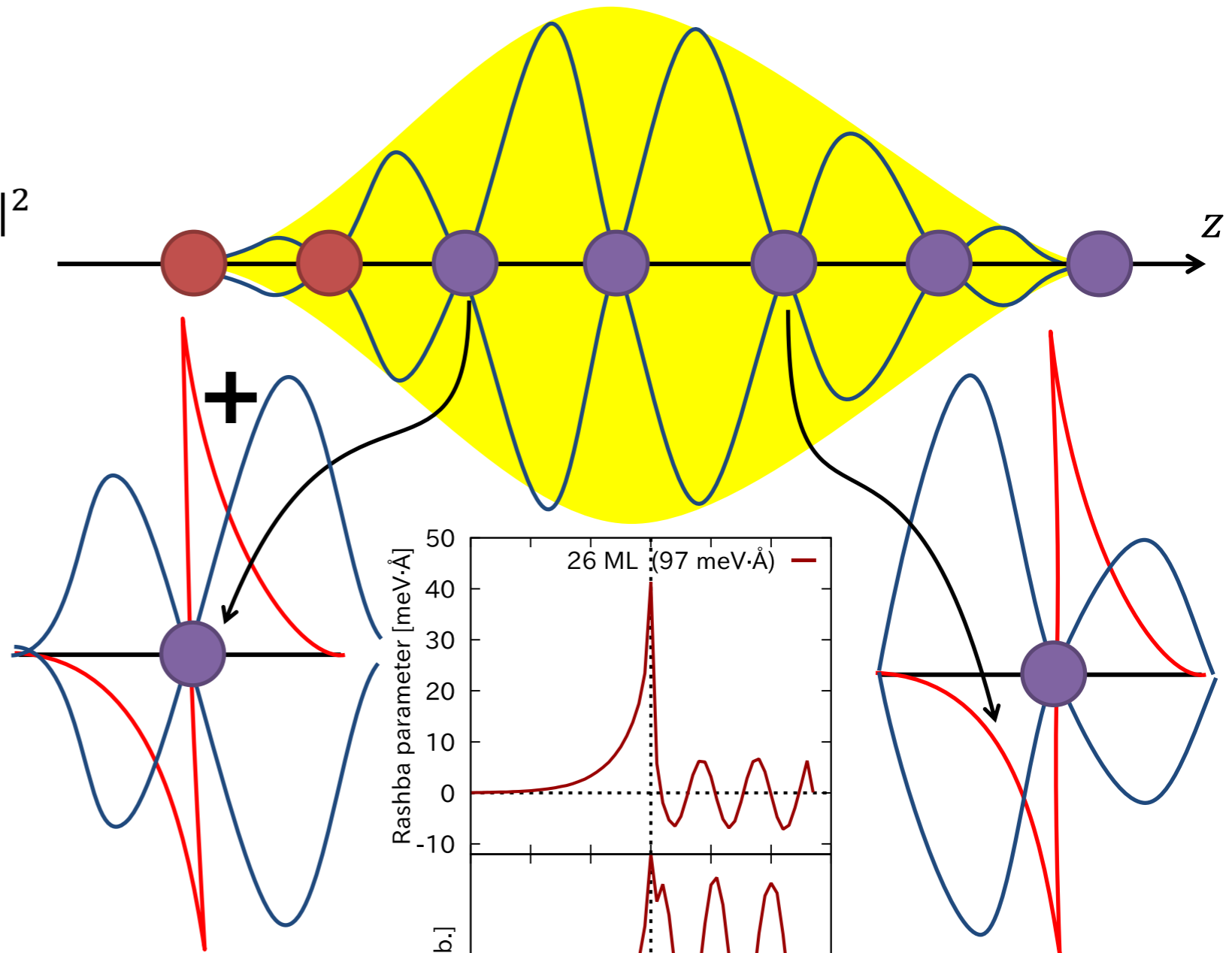
Large in the
vicinity of atoms



M. Nagano *et al.*,
J. Phys.: Condens. Matter
21, 064239 (2009).

$$\varphi(\mathbf{r}) \approx \varphi_{pz}(\mathbf{r}) \varphi_{\text{envelope}}(z)$$

$$\Delta\varepsilon_i \propto \left\langle \frac{\partial V}{\partial z} z |\varphi_{pz}|^2 \right\rangle \frac{d|\varphi_{\text{envelope}}|^2}{dz}$$



Split vs $|\varphi(r)|^2$ at boundary Au and Ag

$$\Delta\varepsilon_R \approx \int dz \left\langle \frac{\partial V}{\partial z} z |\varphi_{pz}|^2 \right\rangle \frac{d|\varphi_{\text{emvelope}}|^2}{dz} \quad \langle \delta V \rangle \equiv \left\langle \frac{\partial V}{\partial z} z |\varphi_{pz}|^2 \right\rangle$$

R. Noguchi, M. Kawamura, *et al.*, PRB **104**, L180409 (2021).

$$\approx \langle \delta V \rangle_{\text{Au}} \int_{-\infty}^0 \frac{\partial |\varphi_{\text{emvelope}}|^2}{\partial z} + \langle \delta V \rangle_{\text{Ag}} \int_0^{\infty} \frac{\partial |\varphi_{\text{emvelope}}|^2}{\partial z}$$

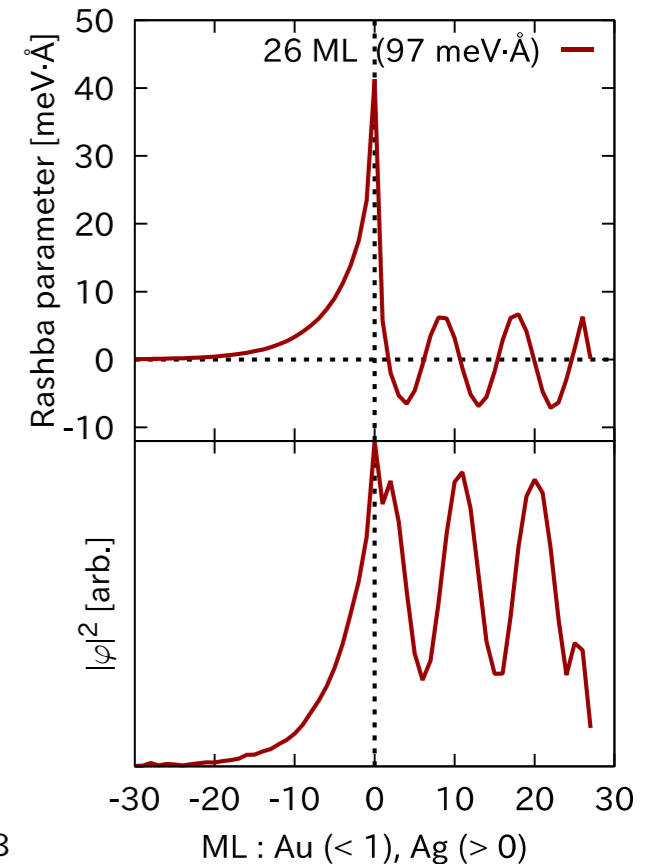
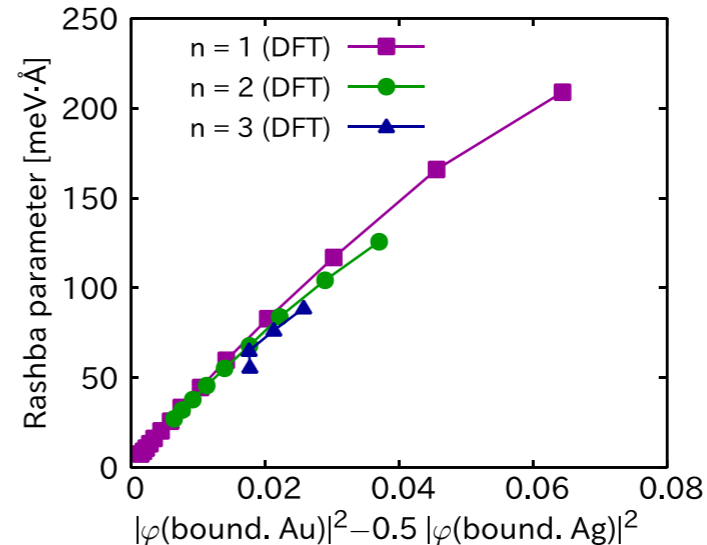
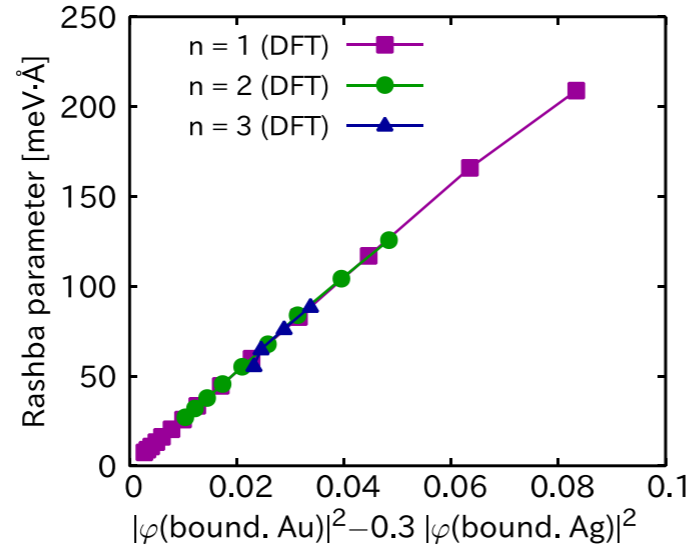
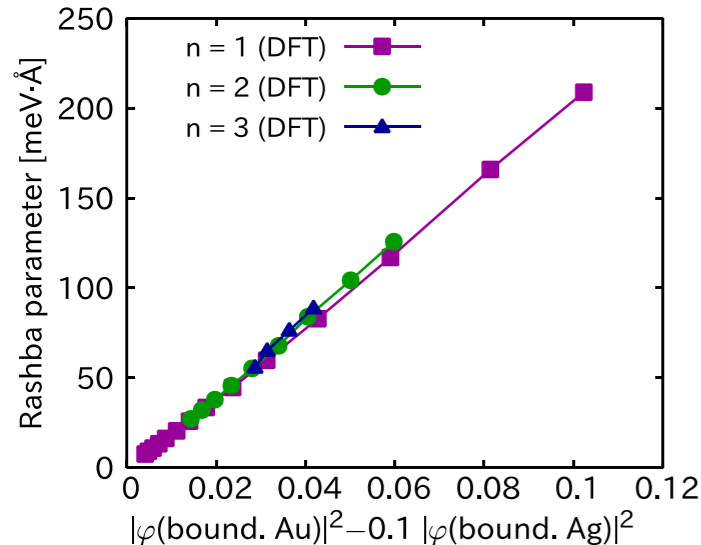
$$= \langle \delta V \rangle_{\text{Au}} |\varphi_{\text{emvelope}}(0)|^2 - \langle \delta V \rangle_{\text{Ag}} |\varphi_{\text{emvelope}}(0)|^2$$

$$\frac{\alpha_{\text{R,Ag}}}{\alpha_{\text{R,Au}}} = \frac{31 \text{ meV} \cdot \text{\AA}}{330 \text{ meV} \cdot \text{\AA}} \approx 0.1$$

SOI coupling constant

Au(6p) : Ag(5p) $\approx 1 : 0.3$

1 : 0.5 $\rightarrow \times$



Further question and motivation

M. Nagano, *et al.*, J. Phys.: Condens. Matter 21, 064239 (2009).

$\psi_{\mathbf{k}}(\mathbf{r}) = e^{i\mathbf{k}\cdot\mathbf{r}}u(z)$ 2D nearly free electronic state

$$\Delta\varepsilon_R = \langle \psi_{\mathbf{k}} | \hat{H}_{\text{SOC}} | \psi_{\mathbf{k}} \rangle = |\mathbf{k}| S_{xy} \int dz 2 \left\langle \frac{\partial V}{\partial z} \right\rangle_{xy} |u(z)|^2$$

- Since the wavefunction of a realistic system is **not like the 2D free electronic** state
- The **applicability** of the earlier study is unclear.
- We need to fill the **gap** between the atomic SOC and Rashba interaction term.
- precise theoretical model to capture the wide range of behavior of QWSs system will be derived.

Spin-orbit coupling and symmetry-broken system

SOC part of Hamiltonian $\hat{H}_{\sigma\sigma'}^{\text{SOC}} = 2(\nabla V(\mathbf{r}) \times \mathbf{p}) \cdot \mathbf{s}_{\sigma\sigma'}$

Uniform spin wavefunction $\begin{pmatrix} \psi_{\mathbf{k}\uparrow}(\mathbf{r}) \\ \psi_{\mathbf{k}\downarrow}(\mathbf{r}) \end{pmatrix} = e^{i\mathbf{k}\cdot\mathbf{r}} \begin{pmatrix} \chi_{\mathbf{k}\uparrow} \\ \chi_{\mathbf{k}\downarrow} \end{pmatrix} u_{\mathbf{k}}(\mathbf{r})$

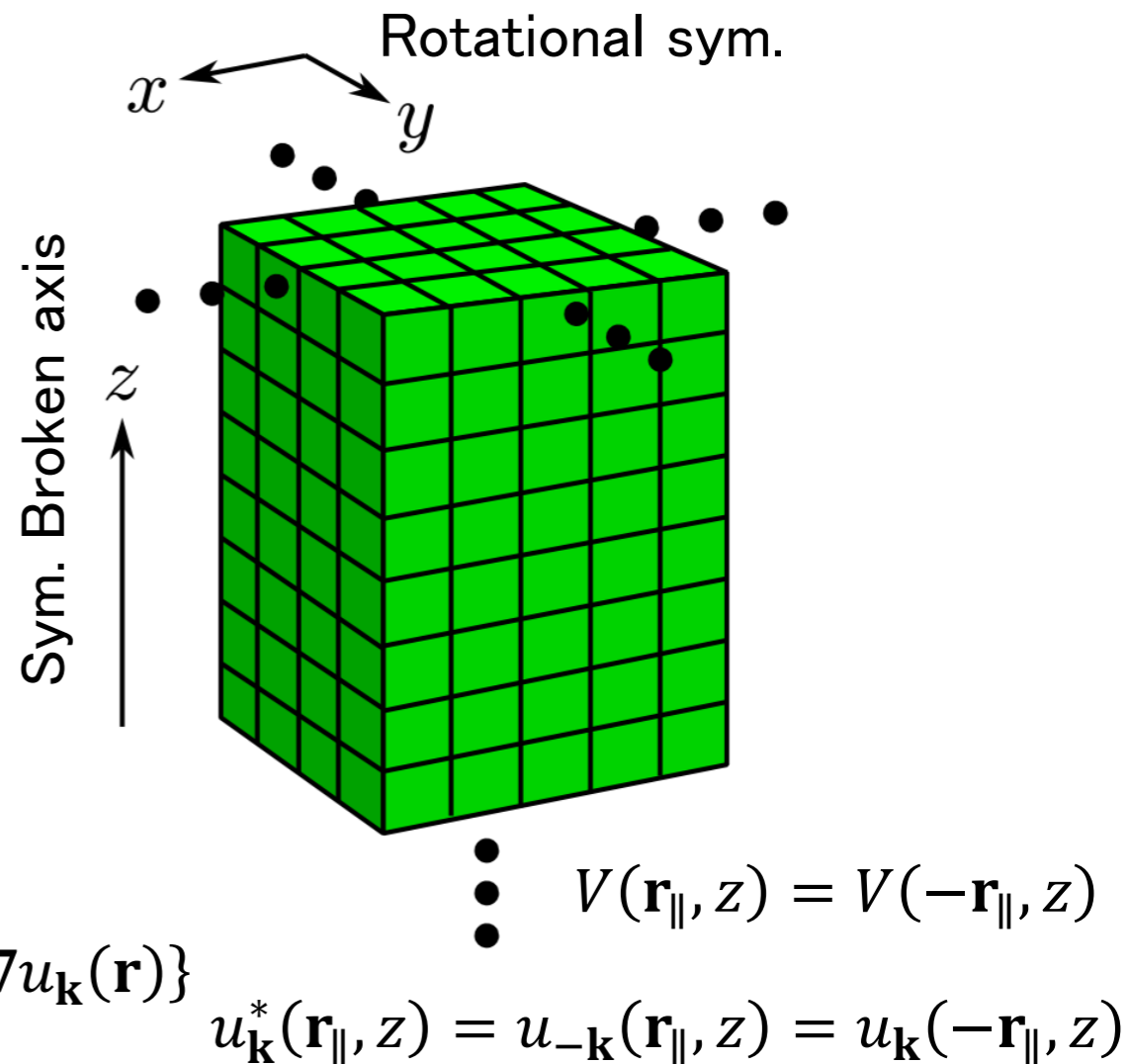
$$\left(-\frac{(\nabla + i\mathbf{k})^2}{2} + V(\mathbf{r}) \right) u_{\mathbf{k}}(\mathbf{r}) = \varepsilon_{\mathbf{k}}^0 u_{\mathbf{k}}(\mathbf{r})$$

$$\varepsilon_{\mathbf{k}}^{\text{SOC}} = \mathbf{s}_{\mathbf{k}} \cdot \int d^3r 2\nabla V(\mathbf{r}) \times \{ \mathbf{k} |u_{\mathbf{k}}(\mathbf{r})|^2 - i u_{\mathbf{k}}^*(\mathbf{r}) \nabla u_{\mathbf{k}}(\mathbf{r}) \}$$

$$= 2\mathbf{s}_{\mathbf{k}} \cdot \int d^3r \{ \nabla V(\mathbf{r}) \times \mathbf{k} |u_{\mathbf{k}}(\mathbf{r})|^2 + i V(\mathbf{r}) \nabla u_{\mathbf{k}}^*(\mathbf{r}) \times \nabla u_{\mathbf{k}}(\mathbf{r}) \}$$

$$(\chi_{\mathbf{k}\uparrow}^*, \chi_{\mathbf{k}\downarrow}^*) \begin{pmatrix} \mathbf{s}_{\uparrow\uparrow} & \mathbf{s}_{\uparrow\downarrow} \\ \mathbf{s}_{\downarrow\uparrow} & \mathbf{s}_{\downarrow\downarrow} \end{pmatrix} \begin{pmatrix} \chi_{\mathbf{k}\uparrow} \\ \chi_{\mathbf{k}\downarrow} \end{pmatrix}$$

Re ← Gauss theorem & anti sym. of \times



Expansion of $u_{\mathbf{k}}(\mathbf{r})$ for \mathbf{k}

$$u_{\mathbf{k}}(\mathbf{r}) = u_0(\mathbf{r}) + \sum_i k_i \partial_{k_i} u_{\mathbf{k}}(\mathbf{r}) \Big|_{\mathbf{k}=\mathbf{0}} + \sum_{ij} k_i k_j \partial_{k_i} \partial_{k_j} u_{\mathbf{k}}(\mathbf{r}) \Big|_{\mathbf{k}=\mathbf{0}} + O(k^3)$$

Real

$$\partial_{k_i} u_{\mathbf{k}=\mathbf{0}}(\mathbf{r}) = i \left(-\frac{\nabla^2}{2} + V(\mathbf{r}) - \varepsilon_{\mathbf{k}=\mathbf{0}} \right)^{-1} \partial_{r_i} u_0(\mathbf{r}) \quad \text{Imaginary}$$

$$\partial_{k_i} \partial_{k_j} u_{\mathbf{k}=\mathbf{0}}(\mathbf{r}) \quad \text{Real}$$

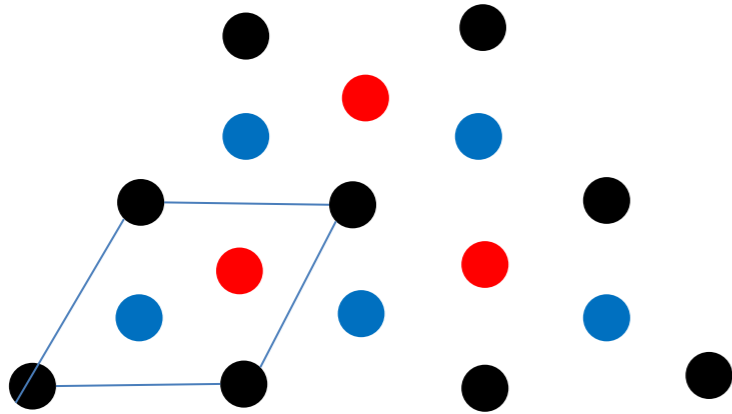
$$= i \left(-\frac{\nabla^2}{2} + V(\mathbf{r}) - \varepsilon_{\mathbf{k}=\mathbf{0}} \right)^{-1} \left\{ \left(\partial_{k_i} \partial_{k_j} \varepsilon_{\mathbf{k}=\mathbf{0}} - \delta_{ij} \right) u_0(\mathbf{r}) + i \partial_{r_j} \partial_{k_i} u_{\mathbf{k}=\mathbf{0}}(\mathbf{r}) + i \partial_{r_i} \partial_{k_j} u_{\mathbf{k}=\mathbf{0}}(\mathbf{r}) \right\}$$

$$u_{\mathbf{k}}^*(\mathbf{r}) = u_0(\mathbf{r}) - \sum_i \partial_{k_i} u_{\mathbf{k}}(\mathbf{r}) \Big|_{\mathbf{k}=\mathbf{0}} + \sum_{ij} \partial_{k_i} \partial_{k_j} u_{\mathbf{k}}(\mathbf{r}) \Big|_{\mathbf{k}=\mathbf{0}} + O(k^3)$$

$$\varepsilon_{\mathbf{k}}^{\text{SOC}} = 2\mathbf{s}_{\mathbf{k}} \cdot \int d^3r \left\{ \nabla V(\mathbf{r}) \times \mathbf{k} |u_0(\mathbf{r})|^2 + 2iV(\mathbf{r}) \nabla u_0(\mathbf{r}) \times \nabla \sum_i k_i \partial_{k_i} u_{\mathbf{k}=\mathbf{0}}(\mathbf{r}) \right\} + O(k^3)$$

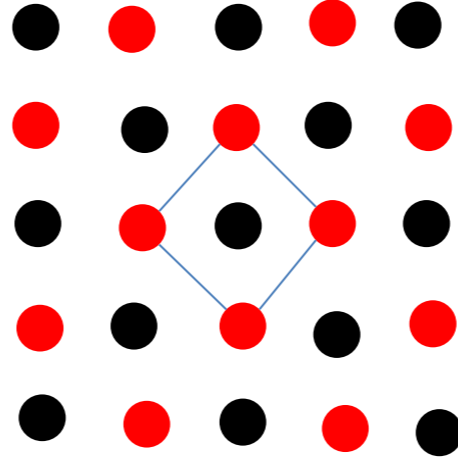
Symmetry

(111) surface of fcc lattice



3-fold + 3 mirrors

(100) surface of cubic lattice



4-fold + 4 mirrors

Symmetry op.

$$u_0(\hat{R}\mathbf{r}) = u_0(\mathbf{r})$$

$$\nabla_{\mathbf{r}} u_0(\mathbf{r}) \rightarrow \hat{R}^{-t} \nabla_{\mathbf{r}} u_0(\hat{R}\mathbf{r})$$

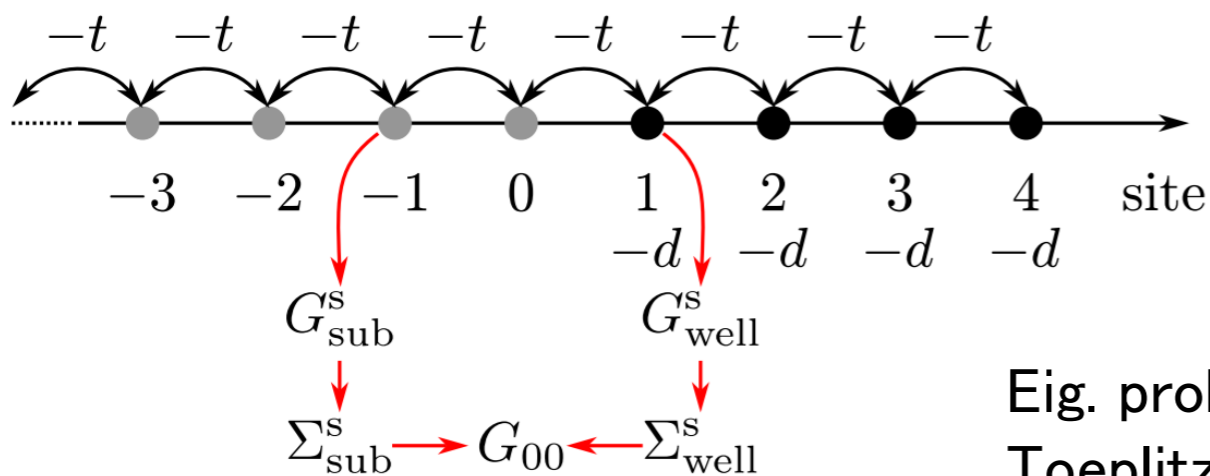
$$\nabla_{\mathbf{k}} u_{\mathbf{k}=0}(\hat{R}\mathbf{r}) = \hat{R}^{-t} \nabla_{\mathbf{k}} u_{\mathbf{k}=0}(\mathbf{r})$$

$$\begin{aligned} \varepsilon_{\mathbf{k}}^{\text{SOC}} &= 2\mathbf{s}_{\mathbf{k}} \cdot (\mathbf{e}_z \times \mathbf{k}) \int d^3r \left\{ \frac{\partial V(\mathbf{r})}{\partial z} |u_0(\mathbf{r})|^2 + iV(\mathbf{r}) \left(\frac{\partial u_0(\mathbf{r})}{\partial z} \nabla_{\mathbf{r}} \cdot \nabla_{\mathbf{k}} u_{\mathbf{k}=0}(\mathbf{r}) - \nabla_{\mathbf{r}} u_0(\mathbf{r}) \cdot \frac{\partial \nabla_{\mathbf{k}} u_{\mathbf{k}=0}(\mathbf{r})}{\partial z} \right) \right\} \\ &+ O(k^3) \end{aligned}$$

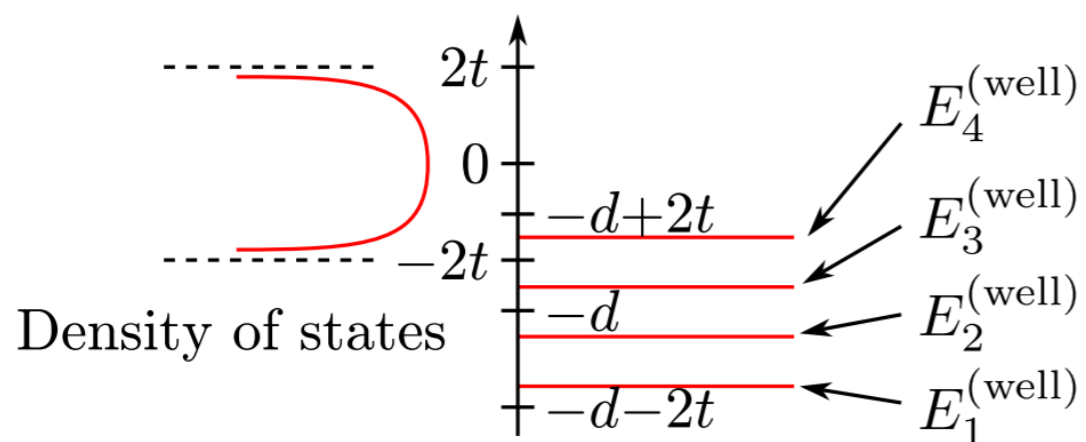
Intrinsic magnetic field in $x - y$ plane and parallel to $\mathbf{e}_z \times \mathbf{k}$

Assuming $\nabla_{\mathbf{k}} u_{\mathbf{k}=0}(\mathbf{r}) = 0$, this becomes Nagano's formula

Tight-binding model



Eig. problem of
Toeplitz matrix



$$\text{Res}_{\varepsilon=\varepsilon_n} [G_{00}(\varepsilon)] = \frac{\sqrt{4e_2(1-e_0) + (e_1 - E_n^{(\text{well})})^2} - (e_1 - E_n^{(\text{well})})}{2(1-e_0)\sqrt{4e_2(1-e_0) + (e_1 - E_n^{(\text{well})})^2}}$$

Function of d/t

$$|u_{\text{env}}(z_b)|^2 \approx |\langle 0|u_n\rangle|^2 = \text{Res}_{\varepsilon=\varepsilon_n} [G_{00}(\varepsilon)]$$

$$G_{00}(\varepsilon) = \frac{1}{\varepsilon - \Sigma_{\text{sub}}^s - \Sigma_{\text{well}}^s}$$

$$E_n^{(\text{well})} \equiv -d - 2t \cos\left(\frac{n\pi}{N_{\text{well}} + 1}\right)$$

$$e_2 \equiv \frac{2t^2}{N_{\text{well}} + 1} \sin^2\left(\frac{n\pi}{N_{\text{well}} + 1}\right)$$

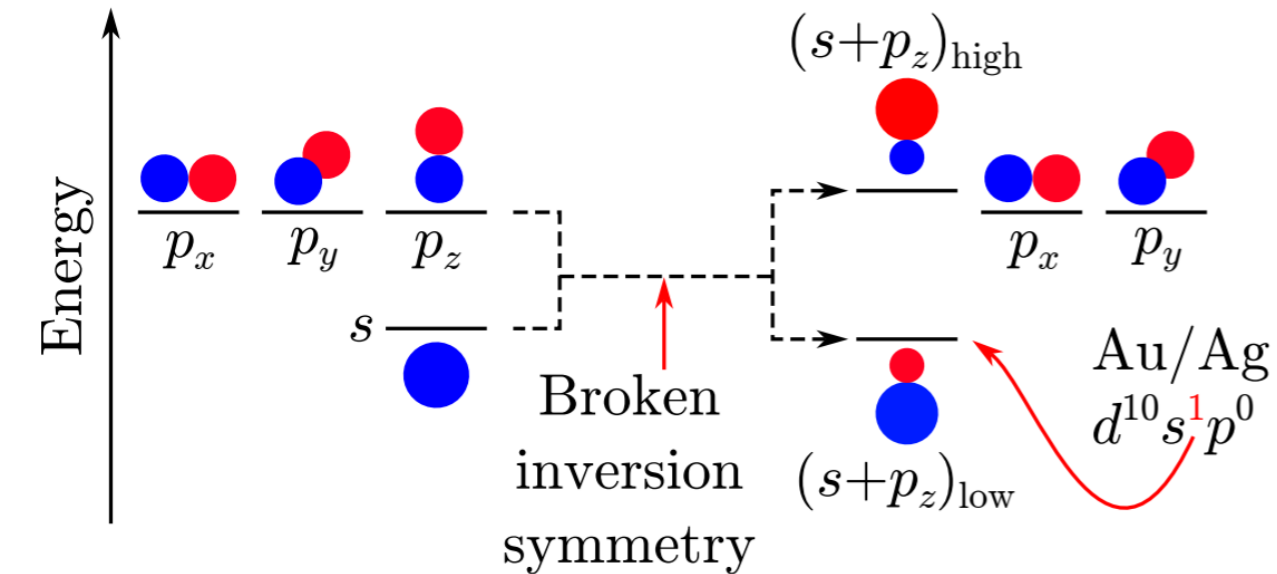
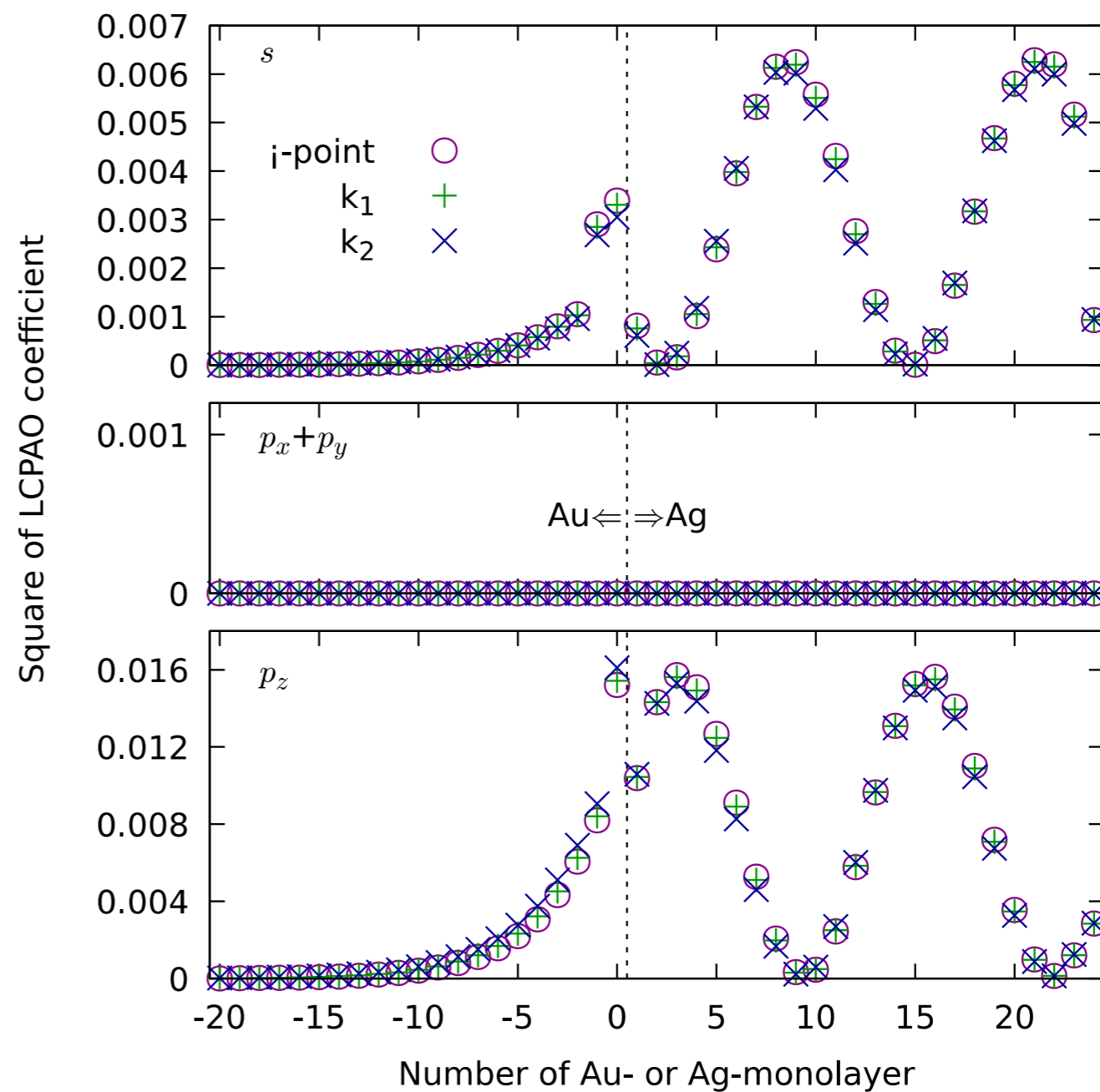
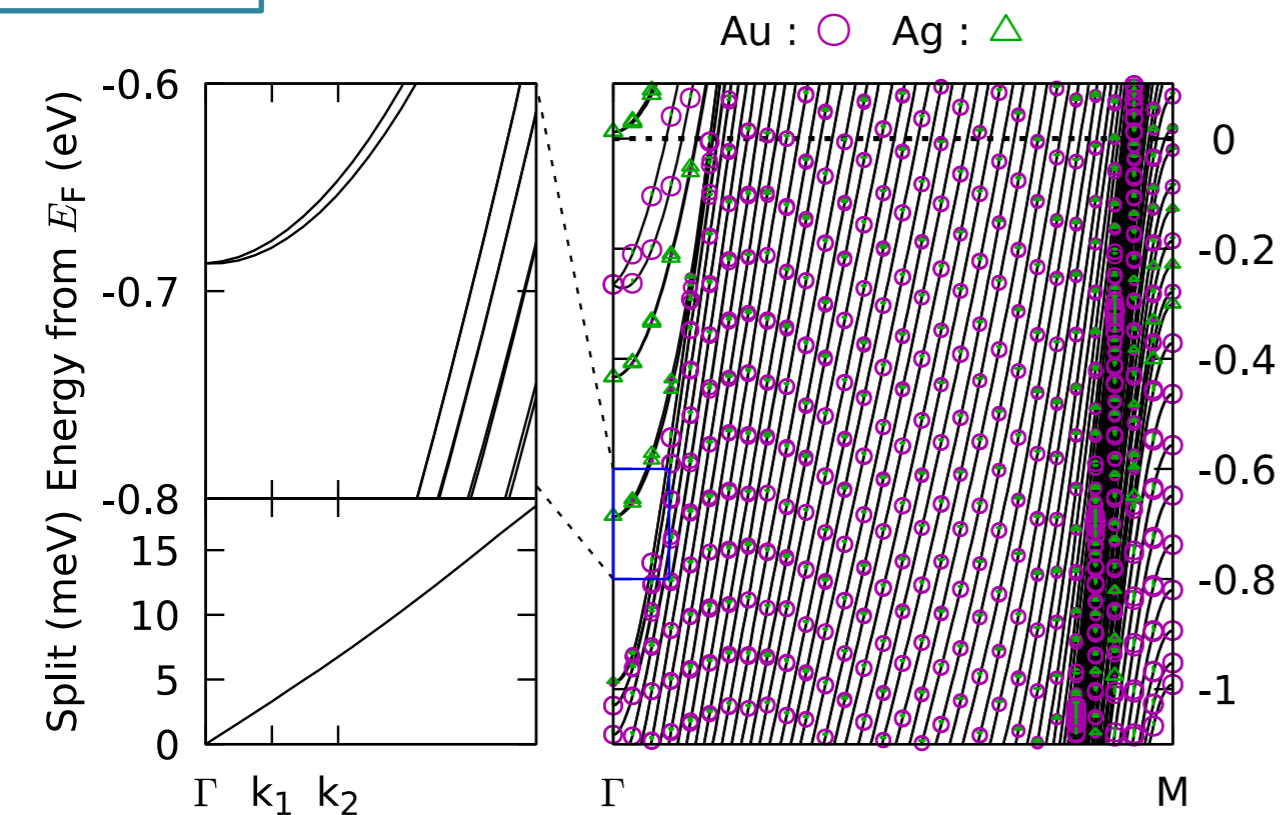
$$e_1 \equiv \frac{1}{2} \left(E_n^{(\text{well})} + \sqrt{E_n^{(\text{well})2} - 4t^2} \right)$$

$$e_0 \equiv \frac{1}{2} + \frac{E_n^{(\text{well})}}{2\sqrt{E_n^{(\text{well})2} - 4t^2}}$$

$$\alpha_R \approx \alpha_R^V \text{Res}_{\varepsilon=\varepsilon_n} [G_{00}(\varepsilon)]$$

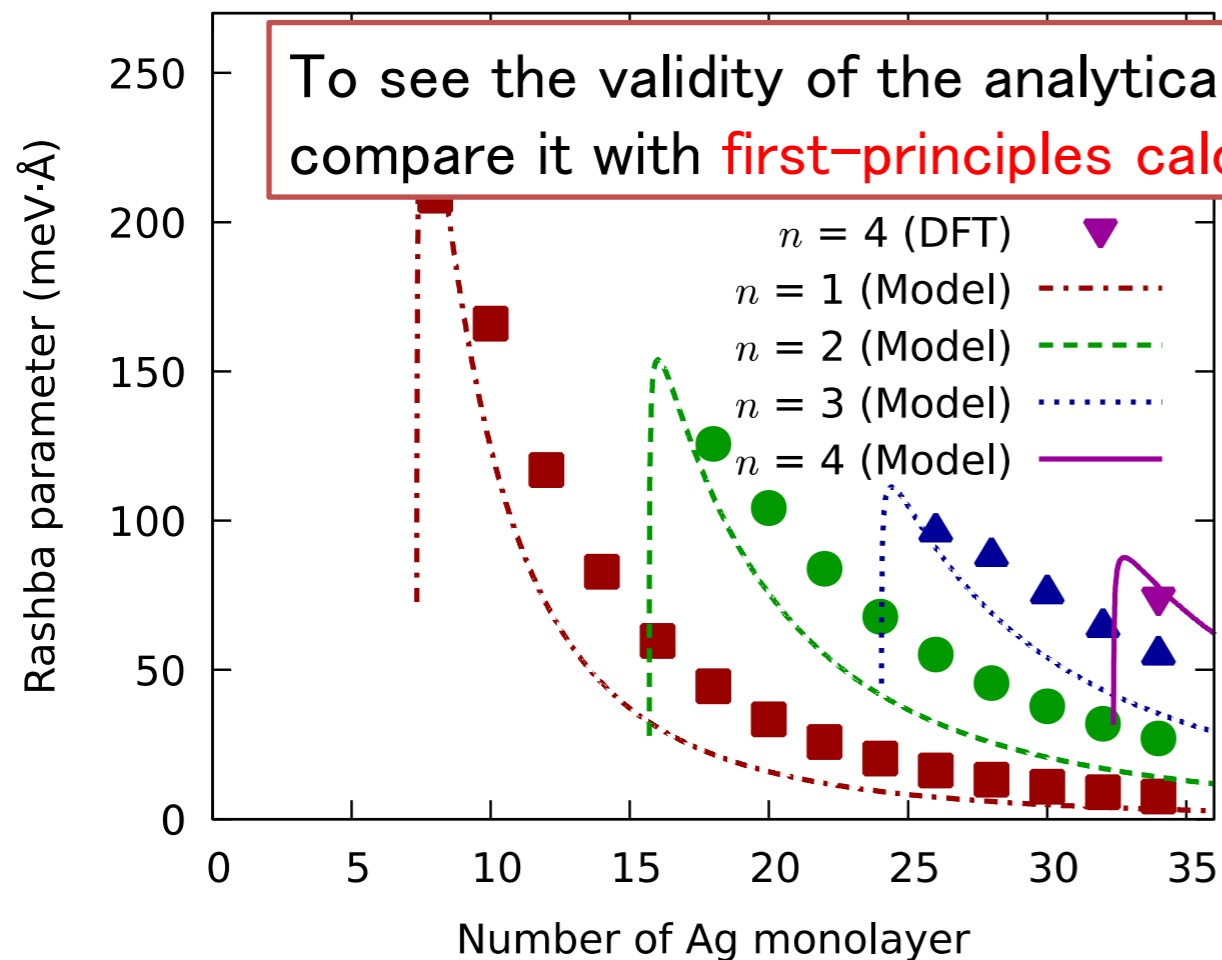
Example

Band structure and orbital character



Validity and efficiency of analytical formula

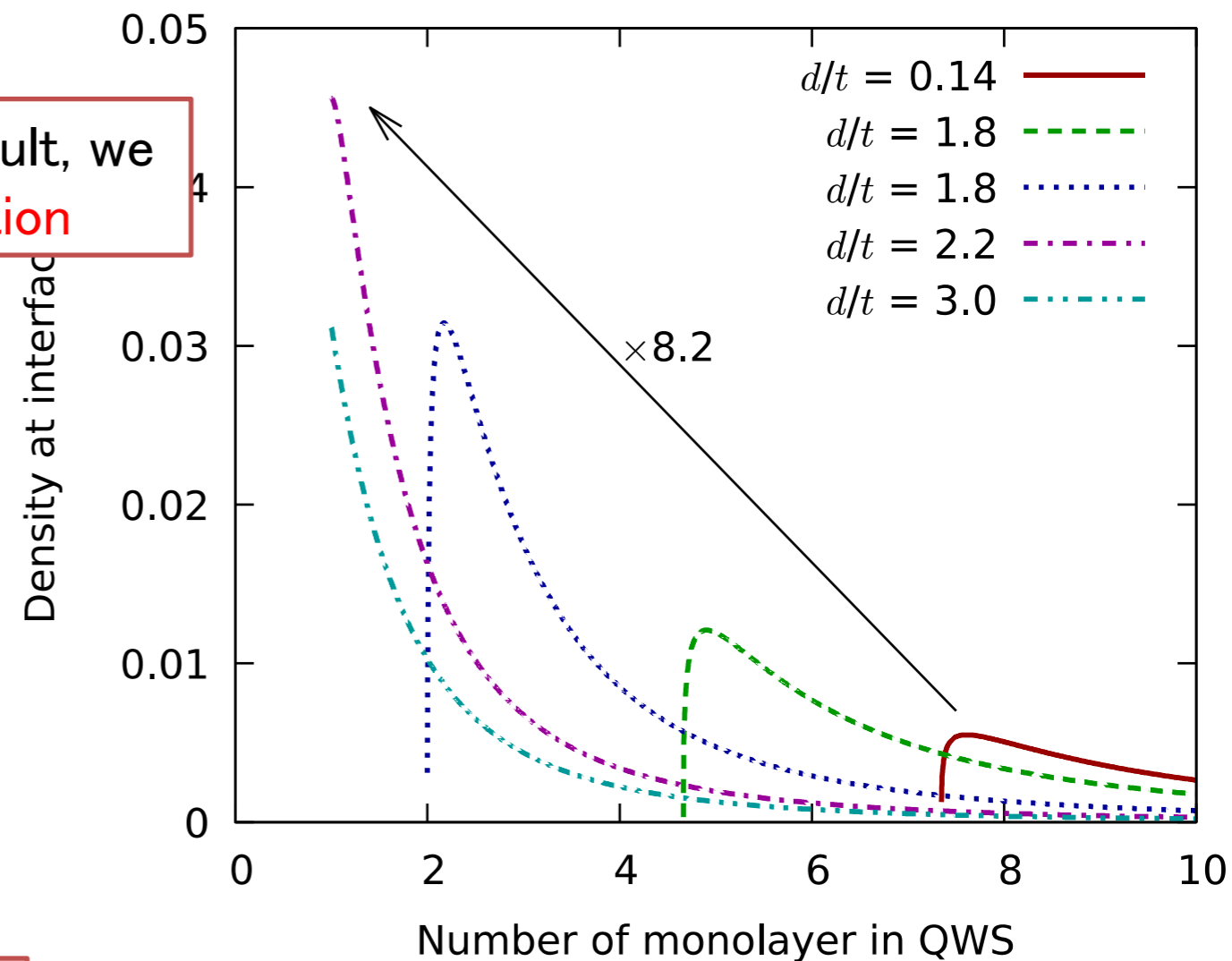
Example



$$\alpha_R \approx \alpha_R^V \text{Res}_{\varepsilon=\varepsilon_n} [G_{00}(\varepsilon)]$$

$$\alpha_R^V = 47,000 \text{ (meV} \cdot \text{Å)}, d/t = 0.14$$

Two fitting
params.



Max. at $N_{\text{well}} = 1$

Bi(1/3ML) surface alloy : C. R. Ast, *et al.*, PRL 98, 186807 (2007).

Bi (1ML) on Cu(111) : S. Mathias, *et al.*, PRL 104, 066802 (2010).

Summary

- We computed Ag/Au(111) slab model (Au 60 ML + Ag 6~34 ML).
 - We reproduced quantitatively the experimental Rashba splitting (the same **ML number and well state dependence**).
 - We decomposed the splitting parameter α_R into **contributions from each atom**.
 - α_R can be estimated with $|\varphi(r)|^2$ at boundary-Au/Ag and $\langle \partial V / \partial z \rangle$ of each element. Therefore the **Rashba effect mainly occurs at the boundary** of this system.
 - We constructed **minimum tight-binding model** which can explain the trend of α_R .
- R. Noguchi, K. Kuroda, M. Kawamura, K. Yaji, A. Harasawa, T. Iimori,
S. Shin, F. Komori, T. Ozaki, T. Kondo, PRB **104**, L180409 (2021).
- We construct the theory to obtain the **\mathbf{k} -linear Rashba splitting energy** systematically from the SOC.
 - Then, we derive a **minimum model** that captures the Rashba effect in QWS using a **one-dimensional tight-binding model** and the **Green's function** method.
 - Our theory qualitatively fits the first-principles result of a realistic Ag/Au(111) system using only **two fitting parameters**.

